

# BQ2057, BQ2057x Advanced Linear Charge Management ICs for Single- and Two-Cell Lithium-Ion and Lithium-Polymer

## 1 Features

- Ideal for single (4.1 V or 4.2 V) and dual-cell (8.2 V or 8.4 V) Li-ion or Li-pol packs
- Requires small number of external components
- 0.3-V dropout voltage for minimizing heat dissipation
- Better than  $\pm 1\%$  voltage regulation accuracy with preset voltages
- AutoCompM dynamic compensation of battery pack's internal impedance to reduce charge time
- Optional cell-temperature monitoring before and during charge
- Integrated voltage and current regulation with programmable charge-current and high- or low-side current sensing
- Integrated cell conditioning for reviving deeply discharged cells and minimizing heat dissipation during initial stage of charge
- Charge status output for single or dual led or host processor interface
- Automatic battery-recharge feature
- Charge termination by minimum current
- Automatic low-power sleep mode when  $V_{CC}$  is removed
- EVMs available for quick evaluation
- Packaging: 8-pin SOIC, 8-pin TSSOP, 8-pin MSOP

## 2 Applications

- Emergency Call Systems, Telematics control unit
- Aftermarket Telematics
- Gaming and Computer Accessories
- Portable Medical Equipment
- EPOS Card Reader

## 3 Description

The BQ2057 series advanced lithium-ion (Li-ion) and lithium-polymer (Li-pol) linear charge-management ICs are designed for cost-sensitive and compact

portable electronics. They combine high-accuracy current and voltage regulation, battery conditioning, temperature monitoring, charge termination, charge-status indication, and AutoComp™ charge-rate compensation in a single 8-pin IC. MSOP, TSSOP, and SOIC package options are offered to fit a wide range of end applications.

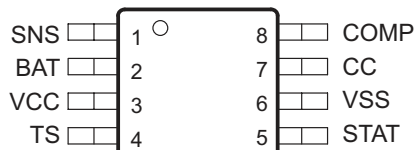
The BQ2057 continuously measures battery temperature using an external thermistor. For safety, the BQ2057 inhibits charge until the battery temperature is within user-defined thresholds. The BQ2057 then charges the battery in three phases: conditioning, constant current, and constant voltage. If the battery voltage is below the low-voltage threshold,  $V_{(min)}$ , the BQ2057 precharges using a low current to condition the battery. The conditioning charge rate is approximately 10% of the regulation current. The conditioning current also minimizes heat dissipation in the external pass-element during the initial stage of the charge. After conditioning, the BQ2057 applies a constant current to the battery. An external sense-resistor sets the current. The sense-resistor can be on either the high or low side of the battery without additional components. The constant-current phase continues until the battery reaches the charge-regulation voltage.

### Device Information

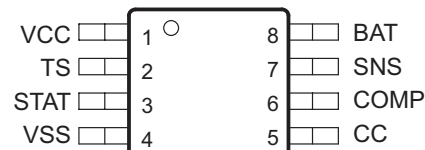
| PART NUMBER                       | PACKAGE <sup>(1)</sup>  | BODY SIZE (NOM)   |
|-----------------------------------|-------------------------|-------------------|
| BQ2057C, BQ2057W                  | SOIC (8)                | 4.90 mm × 3.91 mm |
| BQ2057, BQ2057C, BQ2057T, BQ2057W | TSSOP (8)               | 3.00 mm × 4.40 mm |
| BQ2057, BQ2057C                   | MSOP (8) <sup>(2)</sup> | 3.00 mm × 3.00 mm |

(1) For all available packages, see the orderable addendum at the end of the datasheet.

(2) Note the difference in pinout for this device.



**BQ2057xSN or BQ2057xTS SOIC (SN) or TSSOP (TS) Package Top View**



**BQ2057xDGK MSOP DGK Package Top View**



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## 4 Revision History

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

| <b>Changes from Revision F (July 2002) to Revision G (December 2022)</b>                                                                                                                                                                                                                  | <b>Page</b> |
|-------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|-------------|
| • Added ESD Rating table, Feature Description section, Device Functional Modes, Application and Implementation section, Power Supply Recommendations section, Layout section, Device and Documentation Support section, and Mechanical, Packaging, and Orderable Information section..... | <b>1</b>    |
| • Updated Device Comparison Table.....                                                                                                                                                                                                                                                    | <b>4</b>    |
| • Added thermal information.....                                                                                                                                                                                                                                                          | <b>5</b>    |
| • Added typical characteristics curves.....                                                                                                                                                                                                                                               | <b>8</b>    |
| • Added figure to <a href="#">Section 10.2</a> .....                                                                                                                                                                                                                                      | <b>22</b>   |
| • Added design requirements.....                                                                                                                                                                                                                                                          | <b>22</b>   |
| • Added application curves.....                                                                                                                                                                                                                                                           | <b>23</b>   |
| • Added Layout Guidelines subsections.....                                                                                                                                                                                                                                                | <b>25</b>   |
| • Added layout example.....                                                                                                                                                                                                                                                               | <b>26</b>   |

## 5 Description (continued)

The BQ2057 then begins the constant-voltage phase. The accuracy of the voltage regulation is better than  $\pm 1\%$  over the operating-temperature and supply-voltage ranges. For single and dual cells, the BQ2057 is offered in four fixed-voltage versions: 4.1 V, 4.2 V, 8.2 V, and 8.4 V. Charge stops when the current tapers to the charge termination threshold,  $I_{(TERM)}$ . The BQ2057 automatically restarts the charge if the battery voltage falls below the  $V_{(RCH)}$  threshold.

The designer also may use the AutoComp feature to reduce charging time. This proprietary technique allows safe and dynamic compensation for the internal impedance of the battery pack during charge.

## 6 Device Comparison Table

| T <sub>A</sub> | PACKAGE                   |           |            |                           |
|----------------|---------------------------|-----------|------------|---------------------------|
|                | CHARGE REGULATION VOLTAGE | SOIC (SN) | TSSOP (TS) | MSOP <sup>(1)</sup> (DGK) |
| -20°C to 70°C  | 4.1 V                     | BQ2057SN  | BQ2057TS   | BQ2057DGK                 |
|                | 4.2 V                     | BQ2057CSN | BQ2057CTS  | BQ2057CDGK                |
|                | 8.2 V                     | BQ2057TSN | BQ2057TTS  | Not available             |
|                | 8.4 V                     | BQ2057WSN | BQ2057WTS  |                           |

(1) Note the difference in pinout for this package.

## 7 Pin Configuration and Functions

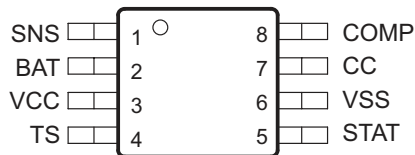


Figure 7-1. BQ2057xSN or BQ2057xTS SOIC (SN) or TSSOP (TS) Package Top View

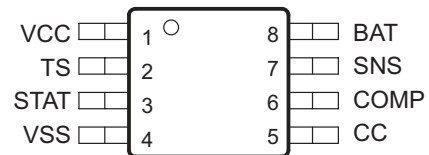


Figure 7-2. BQ2057xDGK MSOP DGK Package Top View

Table 7-1. Pin Functions-

| PIN  |                                |               | I/O | DESCRIPTION                               |
|------|--------------------------------|---------------|-----|-------------------------------------------|
| NAME | NO.                            |               |     |                                           |
|      | SOIC (SN)<br>and<br>TSSOP (TS) | MSOP<br>(DGK) |     |                                           |
| BAT  | 2                              | 8             | I   | Voltage sense input                       |
| CC   | 7                              | 5             | O   | Charge control output                     |
| COMP | 8                              | 6             | I   | Charge-rate compensation input (AutoComp) |
| SNS  | 1                              | 7             | I   | Current sense input                       |
| STAT | 5                              | 3             | O   | Charge status output                      |
| TS   | 4                              | 2             | I   | Temperature sense input                   |
| VCC  | 3                              | 1             | I   | Supply voltage                            |
| VSS  | 6                              | 4             | -   | Ground                                    |

## 8 Specifications

### 8.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted)<sup>(1)</sup>

|                                                             | MIN  | MAX          | UNIT |
|-------------------------------------------------------------|------|--------------|------|
| Supply voltage ( $V_{CC}$ with respect to GND)              | -0.3 | 18           | V    |
| Input voltage, SNS, BAT, TS, COMP (all with respect to GND) | -0.3 | $V_{CC}+0.3$ | V    |
| Sink current (STAT pin) not to exceed $P_D$                 |      | 20           | mA   |
| Source current (STAT pin) not to exceed $P_D$               |      | 10           | mA   |
| Output current (CC pin) not to exceed $P_D$                 |      | 40           | mA   |
| $P_D$ Total power dissipation (at 25°C)                     |      | 300          | mW   |
| $T_A$ Operating free-air temperature range                  | -20  | 70           | °C   |
| $T_{stg}$ Storage temperature                               | -40  | 125          | °C   |

- (1) Stresses beyond those listed under *Absolute Maximum Ratings* may cause permanent damage to the device. These are stress ratings only, which do not imply functional operation of the device at these or any other conditions beyond those indicated under *Recommended Operating Conditions*. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

### 8.2 ESD Ratings

|                                     |                                                                                | VALUE | UNIT |
|-------------------------------------|--------------------------------------------------------------------------------|-------|------|
| $V_{(ESD)}$ Electrostatic discharge | Human-body model (HBM), per ANSI/ESDA/JEDEC JS-001 <sup>(1)</sup>              | ±2000 | V    |
|                                     | Charged-device model (CDM), per JEDEC specification JESD22-C101 <sup>(2)</sup> | ±500  |      |

- (1) JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.  
(2) JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.

### 8.3 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)

|                                            | MIN | NOM | MAX | UNIT |
|--------------------------------------------|-----|-----|-----|------|
| $V_{CC}$ Supply voltage                    | 4.5 |     | 15  | V    |
| $T_A$ Operating free-air temperature range | -20 |     | 70  | °C   |

### 8.4 Thermal Information

| THERMAL METRIC <sup>(1)</sup> |                                              | BQ2057xSN or<br>BQ2057xTS          | BQ2057xDGK<br>MSOP | UNIT |
|-------------------------------|----------------------------------------------|------------------------------------|--------------------|------|
|                               |                                              | SOIC (SN) or TSSOP<br>(TS) PACKAGE | DGK PACKAGE        |      |
|                               |                                              | 8 PINS                             | 8 PINS             |      |
| $R_{\theta JA}$               | Junction-to-ambient thermal resistance       | 157.1                              | 121.9              | °C/W |
| $R_{\theta JC(top)}$          | Junction-to-case (top) thermal resistance    | 46.5                               | 58.8               | °C/W |
| $R_{\theta JB}$               | Junction-to-board thermal resistance         | 89.6                               | 65.8               | °C/W |
| $\Psi_{JT}$                   | Junction-to-top characterization parameter   | 3.3                                | 12.8               | °C/W |
| $\Psi_{JB}$                   | Junction-to-board characterization parameter | 87.4                               | 65.0               | °C/W |
| $R_{\theta JC(bot)}$          | Junction-to-case (bottom) thermal resistance | NA                                 | NA                 | °C/W |

- (1) For more information about traditional and new thermal metrics, see the *Semiconductor and IC Package Thermal Metrics* application report, [SPRA953](#).

## 8.5 Electrical Characteristics

over operating free-air temperature range (unless otherwise noted)

| PARAMETER                                                |                                             | TEST CONDITIONS                                                                                                                                 | MIN                           | TYP                           | MAX                           | UNIT |
|----------------------------------------------------------|---------------------------------------------|-------------------------------------------------------------------------------------------------------------------------------------------------|-------------------------------|-------------------------------|-------------------------------|------|
| I(VCC)                                                   | V <sub>CC</sub> Current                     | V <sub>CC</sub> > V <sub>CC(min)</sub> , Excluding external loads                                                                               |                               | 2                             | 4                             | mA   |
| I(VCCS)                                                  | V <sub>CC</sub> Sleep current               | For BQ2057 and BQ2957C,<br>V <sub>(BAT)</sub> ≥ V <sub>(min)</sub> , V <sub>(BAT)</sub> – V <sub>CC</sub> ≥ 0.8 V                               |                               | 3                             | 6                             | μA   |
|                                                          |                                             | For BQ2057T and BQ2957W,<br>V <sub>(BAT)</sub> ≥ V <sub>(min)</sub> , V <sub>(BAT)</sub> – V <sub>CC</sub> ≥ 0.8 V                              |                               |                               | 10                            |      |
| I <sub>B</sub> (BAT)                                     | Input bias current on BAT pin               | V <sub>(BAT)</sub> = V <sub>(REG)</sub>                                                                                                         |                               |                               | 1                             | μA   |
| I <sub>B</sub> (SNS)                                     | Input bias current on SNS pin               | V <sub>(SNS)</sub> = 5 V                                                                                                                        |                               |                               | 5                             | μA   |
| I <sub>B</sub> (TS)                                      | Input bias current on TS pin                | V <sub>(TS)</sub> = 5 V                                                                                                                         |                               |                               | 5                             | μA   |
| I <sub>B</sub> (COMP)                                    | Input bias current on COMP pin              | V <sub>(COMP)</sub> = 5 V                                                                                                                       |                               |                               | 5                             | μA   |
| BATTERY VOLTAGE REGULATION                               |                                             |                                                                                                                                                 |                               |                               |                               |      |
| V <sub>O</sub> (REG)                                     | Output voltage                              | BQ2057, See (1) (2) (3)                                                                                                                         | 4.059                         | 4.10                          | 4.141                         | V    |
|                                                          |                                             | BQ2057C, See (1) (2) (3)                                                                                                                        | 4.158                         | 4.20                          | 4.242                         |      |
|                                                          |                                             | BQ2057T, See (1) (2) (3)                                                                                                                        | 8.119                         | 8.20                          | 8.282                         |      |
|                                                          |                                             | BQ2057W, See (1) (2) (3)                                                                                                                        | 8.317                         | 8.40                          | 8.484                         |      |
| CURRENT REGULATION                                       |                                             |                                                                                                                                                 |                               |                               |                               |      |
| V <sub>(SNS)</sub>                                       | Current regulation threshold                | BQ2057 and BQ2057C,<br>High-side current sensing configuration                                                                                  | 95.4                          | 105                           | 115.5                         | mV   |
|                                                          |                                             | BQ2057T and BQ2057W,<br>High-side current sensing configuration                                                                                 | 103.6                         | 125                           | 137.5                         |      |
|                                                          |                                             | BQ2057 and BQ2057C,<br>Low-side current sensing configuration                                                                                   | 100                           | 110                           | 121                           |      |
|                                                          |                                             | BQ2057T and BQ2057W,<br>Low-side current sensing configuration                                                                                  | 108.1                         | 130                           | 143                           |      |
| CHARGE TERMINATION DETECTION                             |                                             |                                                                                                                                                 |                               |                               |                               |      |
| I <sub>(TERM)</sub>                                      | Charge termination current detect threshold | Voltage at pin SNS, relative to V <sub>CC</sub> for high-side sensing, and to V <sub>SS</sub> for low-side sensing, 0°C ≤ T <sub>A</sub> ≤ 50°C | –30                           | –14                           | –4                            | mV   |
| TEMPERATURE COMPARATOR                                   |                                             |                                                                                                                                                 |                               |                               |                               |      |
| V <sub>(TS1)</sub>                                       | Lower temperature threshold                 | TS pin voltage                                                                                                                                  | 29.1                          | 30                            | 30.9                          | %VCC |
| V <sub>(TS2)</sub>                                       | Upper temperature threshold                 |                                                                                                                                                 | 58.3                          | 60                            | 61.8                          |      |
| PRECHARGE COMPARATOR                                     |                                             |                                                                                                                                                 |                               |                               |                               |      |
| V <sub>(min)</sub>                                       | Precharge threshold                         | BQ2057                                                                                                                                          | 2.94                          | 3                             | 3.06                          | V    |
|                                                          |                                             | BQ2057C                                                                                                                                         | 3.04                          | 3.1                           | 3.16                          |      |
|                                                          |                                             | BQ2057T                                                                                                                                         | 5.9                           | 6.1                           | 6.22                          |      |
|                                                          |                                             | BQ2057W                                                                                                                                         | 6.18                          | 6.3                           | 6.43                          |      |
| PRECHARGE CURRENT REGULATION                             |                                             |                                                                                                                                                 |                               |                               |                               |      |
| I <sub>(PRECHG)</sub>                                    | Precharge current regulation                | Voltage at pin SNS, relative to V <sub>CC</sub> for high-side sensing, and to V <sub>SS</sub> for low-side sensing, 0°C ≤ T <sub>A</sub> ≤ 50°C |                               | 13                            |                               | mV   |
|                                                          |                                             | Voltage at pin SNS, relative to V <sub>CC</sub> for high-side sensing, 0°C ≤ T <sub>A</sub> ≤ 50°C, V <sub>CC</sub> = 5 V                       | 3                             | 13                            | 22                            | mV   |
| V <sub>RCH</sub> COMPARATOR (Battery Recharge Threshold) |                                             |                                                                                                                                                 |                               |                               |                               |      |
| V <sub>(RCH)</sub>                                       | Recharge threshold                          | BQ2057 and BQ2057C                                                                                                                              | V <sub>O</sub> (REG) – 98 mV  | V <sub>O</sub> (REG) – 100 mV | V <sub>O</sub> (REG) – 102 mV | V    |
|                                                          |                                             | BQ2057T and BQ2057W                                                                                                                             | V <sub>O</sub> (REG) – 196 mV | V <sub>O</sub> (REG) – 200 mV | V <sub>O</sub> (REG) – 204 mV | V    |
| CHARGE-RATE COMPENSATION (AutoComp)                      |                                             |                                                                                                                                                 |                               |                               |                               |      |
| G <sub>(COMP)</sub>                                      | AutoComp gain                               | V <sub>(BAT)</sub> +0.3 V ≤ V <sub>CC</sub> ≤ V <sub>CC(max)</sub> , BQ2057, BQ2057C, BQ2057T, BQ2057W                                          | 1.87                          | 2.2                           | 2.53                          | V/V  |
|                                                          |                                             | V <sub>(BAT)</sub> +0.3 V ≤ V <sub>CC</sub> ≤ V <sub>CC(max)</sub> , BQ2057T and BQ2057W in low-side sensing configuration                      | 2.09                          | 2.4                           | 2.76                          |      |
| STAT PIN                                                 |                                             |                                                                                                                                                 |                               |                               |                               |      |

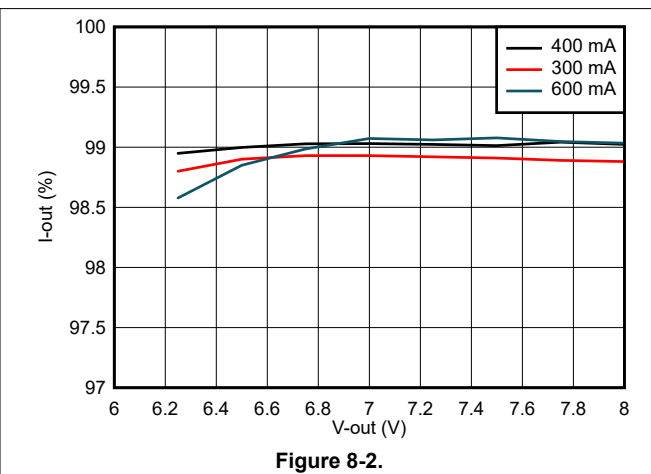
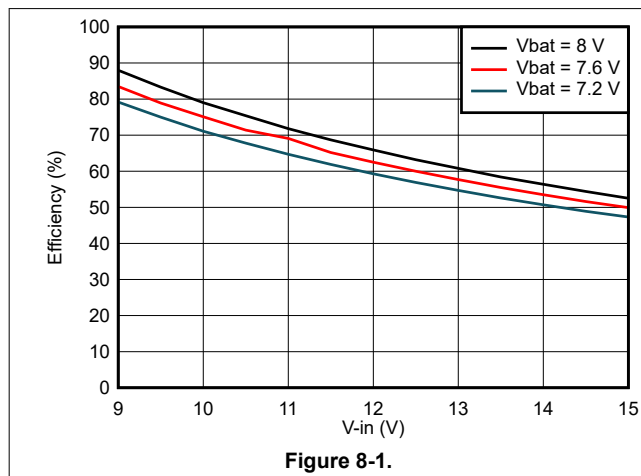
## 8.5 Electrical Characteristics (continued)

over operating free-air temperature range (unless otherwise noted)

| PARAMETER             |                       | TEST CONDITIONS                                            | MIN                  | TYP | MAX | UNIT |    |
|-----------------------|-----------------------|------------------------------------------------------------|----------------------|-----|-----|------|----|
| V <sub>OL(STAT)</sub> | Output (low) voltage  | I <sub>OL</sub> = 10 mA                                    |                      |     | 0.7 | V    |    |
| V <sub>OH(STAT)</sub> | Output (high) voltage | I <sub>OH</sub> = 5 mA                                     | V <sub>CC</sub> –0.5 |     |     |      |    |
| CC PIN                |                       |                                                            |                      |     |     |      |    |
| V <sub>OL(CC)</sub>   | Output low voltage    | I <sub>O(CC)</sub> = 5 mA (sink)                           |                      |     | 1.5 | V    |    |
| I <sub>O(CC)</sub>    | Sink current          | Not to exceed power rating specification (P <sub>D</sub> ) | 5                    |     |     | 40   | mA |

- (1) For high-side current sensing configuration.
- (2) For low-side current sensing configuration, the tolerance is  $\pm 1\%$  for  $T_A = 25^\circ\text{C}$  and  $\pm 1.2\%$  for  $-20^\circ\text{C} \leq T_A \leq 70^\circ\text{C}$ .
- (3)  $V_{\text{(BAT)}} + 0.3 \text{ V} \leq V_{\text{CC}} \leq V_{\text{CC(max)}}$

## 8.6 Typical Characteristics



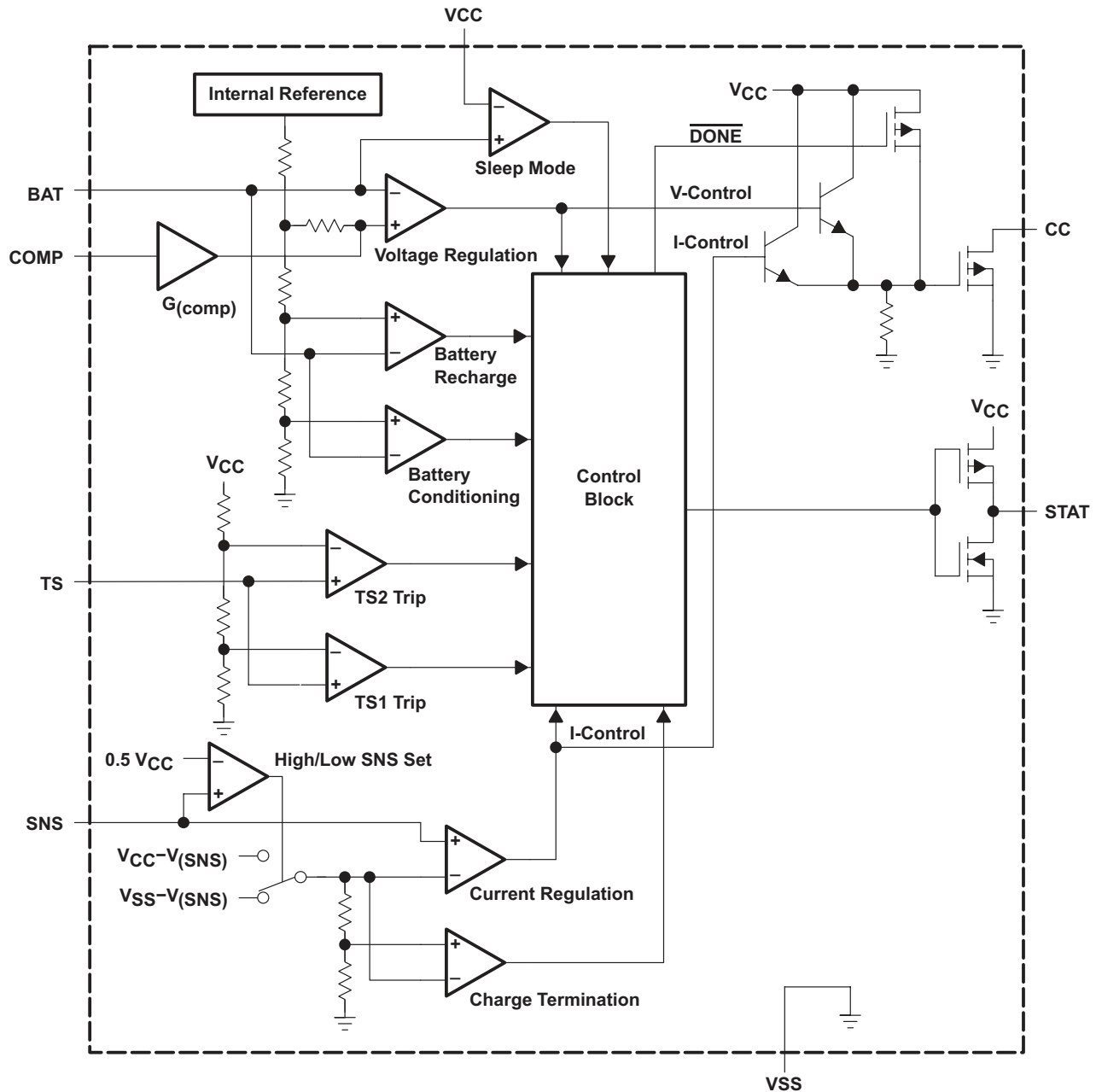


## 9 Detailed Description

### 9.1 Overview

Descriptions of the devices are presented in the following sections.

### 9.2 Functional Block Diagram



### 9.3 Feature Description

#### 9.3.1 Current-Sense Input

Battery current is sensed via the voltage developed on this pin by an external sense resistor. The external resistor can be placed on either the high or low side of the battery. (See schematics for details.)

#### 9.3.2 Battery-Voltage Input

Voltage sense-input tied directly to the positive side of the battery.

### **9.3.3 Temperature Sense Input**

Input for an external battery-temperature monitoring circuit. Connecting this input to VCC/2 disables this feature.

### **9.3.4 Charge-status Output**

Three-state indication of charge in progress, charge complete, and temperature fault or sleep mode.

### **9.3.5 Charge-Control Output**

Source-follower output that drives an external pass-transistor (PNP or P-channel MOSFET) for current and voltage regulation.

### **9.3.6 Charge-Rate Compensation Input**

Sets the charge-rate compensation level. The voltage-regulation output may be programmed to vary as a function of the charge current delivered to the battery.

### **9.3.7 Supply Voltage Input**

Power supply input and current reference for high-side sensing configuration.

## 10 Application and Implementation

### Note

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes. Customers should validate and test their design implementation to confirm system functionality.

### 10.1 Application Information

#### 10.1.1 Functional Description

The BQ2057 is an advanced linear charge controller for single or two-cell Li-Ion or Li-Pol applications. [Figure 10-1](#) shows the schematic of charger using a PNP pass transistor. [Figure 10-2](#) is an operational state diagram, and [Figure 10-3](#) is a typical charge profile. [Figure 10-4](#) shows the schematic of a charger using P-channel MOSFET.

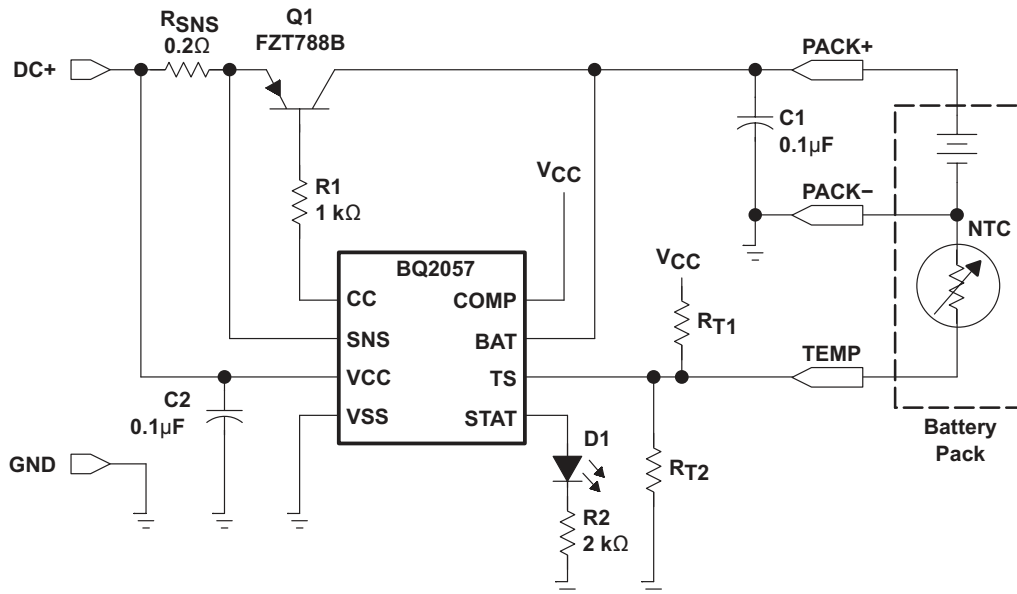


Figure 10-1. Low Dropout Single- or Two-Cell Li-Ion/Li-Pol Charger

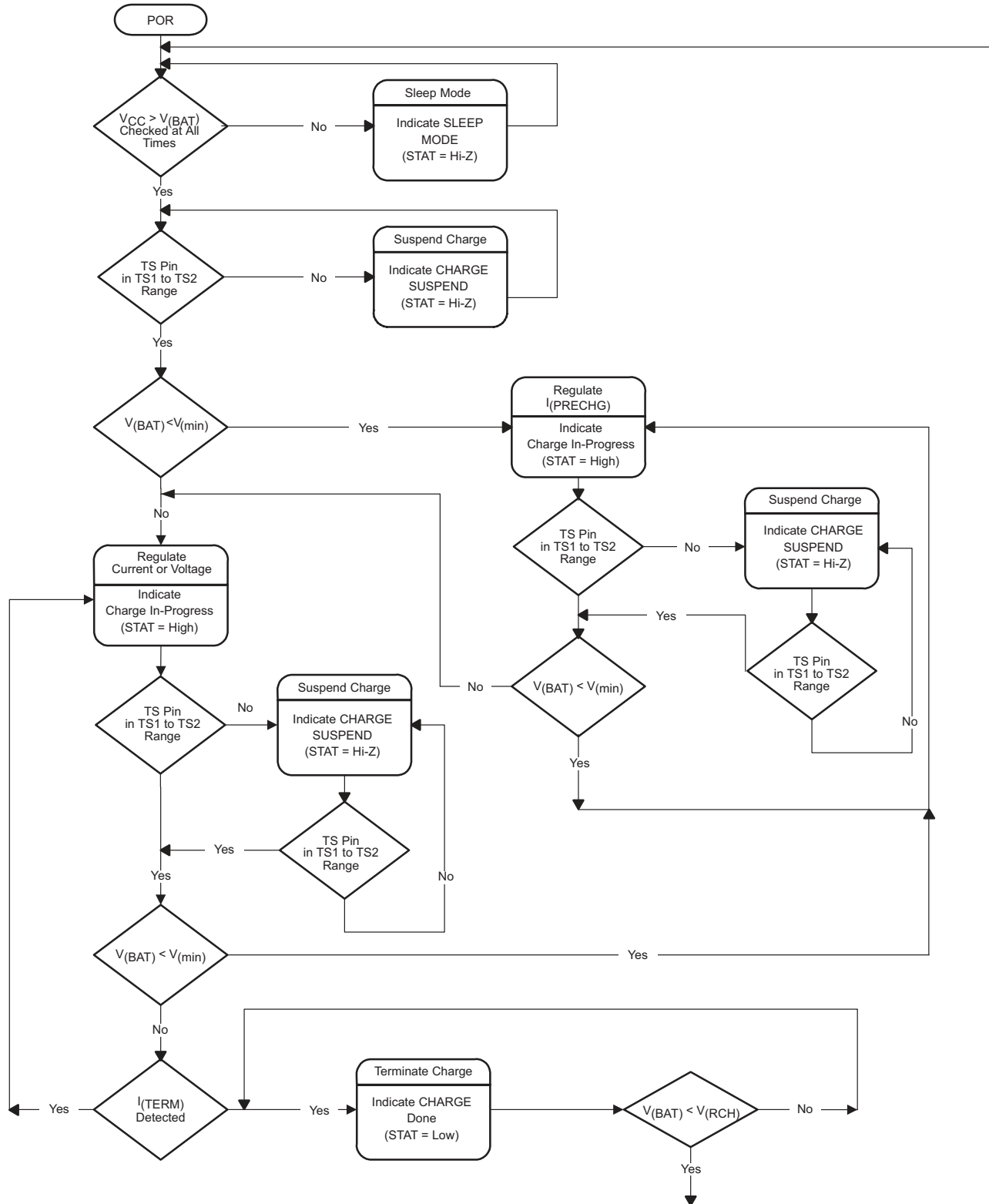
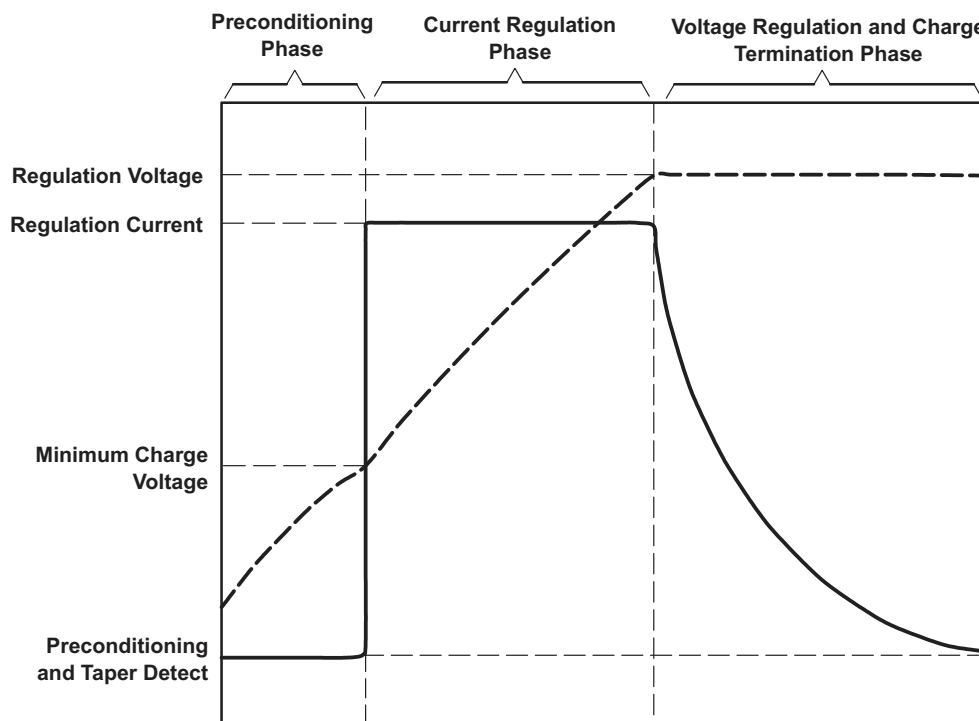


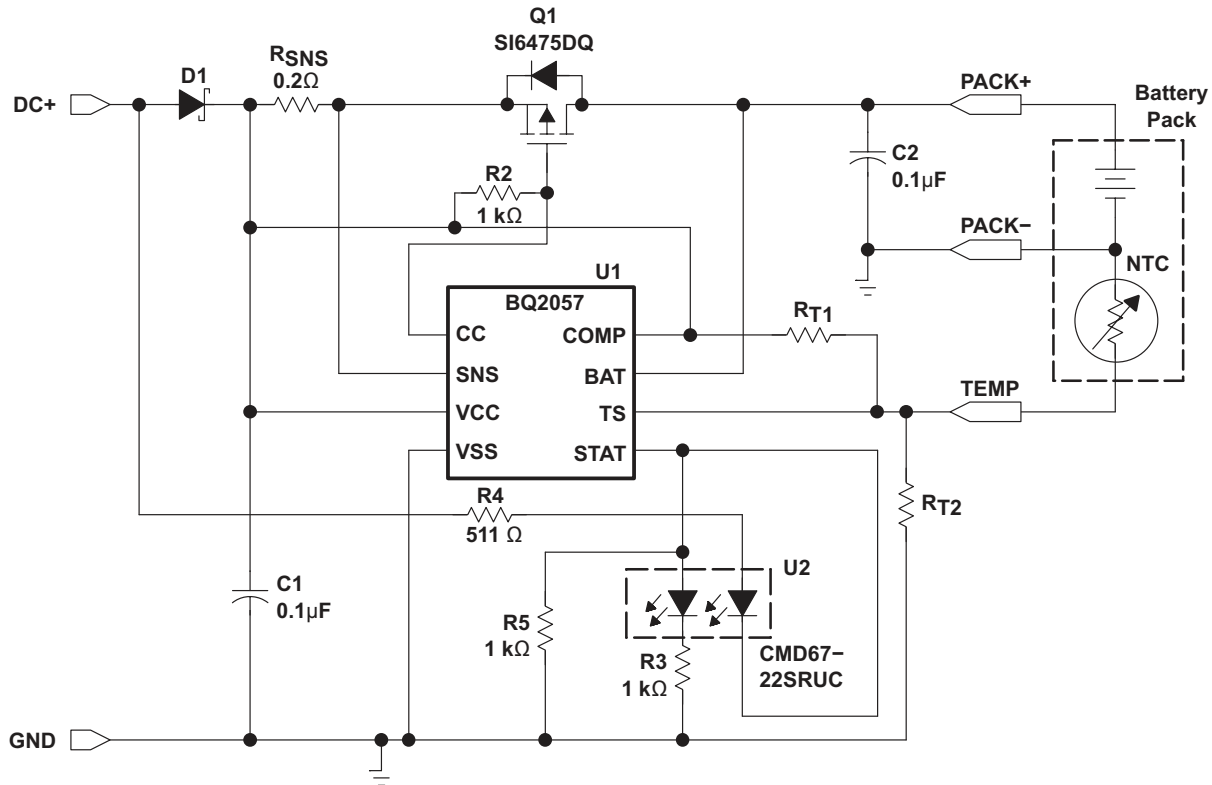
Figure 10-2. Operation Flowchart



**Figure 10-3. Typical Charge Profile**

### 10.1.2 Qualification and Precharge

When power is applied, the BQ2057 starts a charge-cycle if a battery is already present or when a battery is inserted. Charge qualification is based on battery temperature and voltage. The BQ2057 suspends charge if the battery temperature is outside the  $V_{(TS1)}$  to  $V_{(TS2)}$  range and suspends charge until the battery temperature is within the allowed range. The BQ2057 also checks the battery voltage. If the battery voltage is below the precharge threshold  $V_{(min)}$ , the BQ2057 uses precharge to condition the battery. The conditioning charge rate  $I_{(PRECHG)}$  is set at approximately 10% of the regulation current. The conditioning current also minimizes heat dissipation in the external pass-element during the initial stage of charge. See [Figure 10-3](#) for a typical charge-profile.



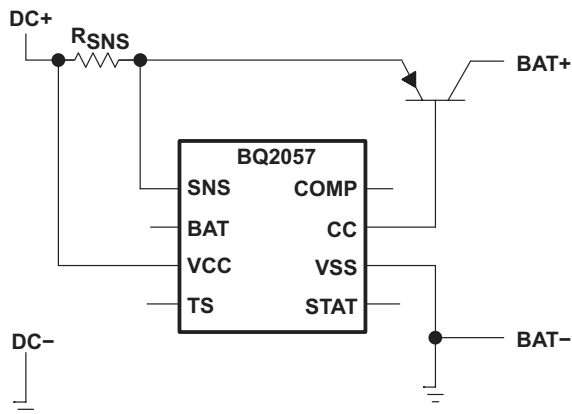
### Figure 10-4. 0.5-A Charger Using P-Channel MOSFET

### 10.1.3 Current Regulation Phase

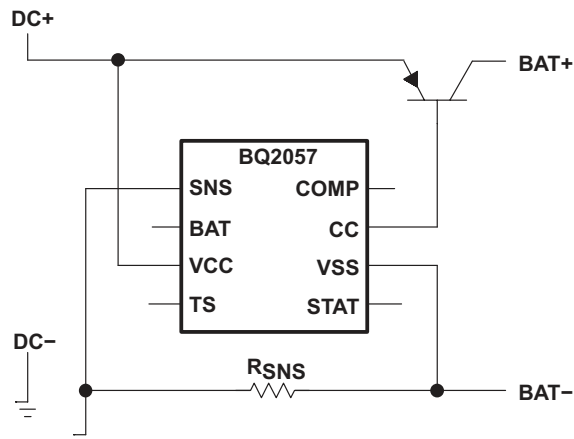
The BQ2057 regulates current while the battery-pack voltage is less than the regulation voltage,  $V_{O(REG)}$ . The BQ2057 monitors charge current at the SNS input by the voltage drop across a sense-resistor,  $R_{SNS}$ , in series with the battery pack. In high-side current sensing configuration (see [Figure 10-5](#)),  $R_{SNS}$  is between the VCC and SNS pins, and in low-side sensing (see [Figure 10-6](#)) the  $R_{SNS}$  is between VSS (battery negative) and SNS (charger ground) pins. Charge-current feedback, applied through pin SNS, maintains a voltage of  $V_{(SNS)}$  across the current sense resistor. [Equation 1](#) calculates the value of the sense resistor:

$$R_{\text{SNS}} = \frac{V_{(\text{SNS})}}{I_{\text{O(REG)}}} \quad (1)$$

Where  $I_{O(REG)}$  is the desired charging current.



**Figure 10-5. High-Side Current Sensing**



**Figure 10-6. Low-Side Current Sensing**

### 10.1.4 Voltage Regulation Phase

The voltage regulation feedback is through the BAT pin. This input is tied directly to the positive side of the battery pack. The BQ2057 monitors the battery-pack voltage between the BAT and VSS pins. The BQ2057 is offered in four fixed-voltage versions: 4.1 V, 4.2 V, 8.2 V, and 8.4 V.

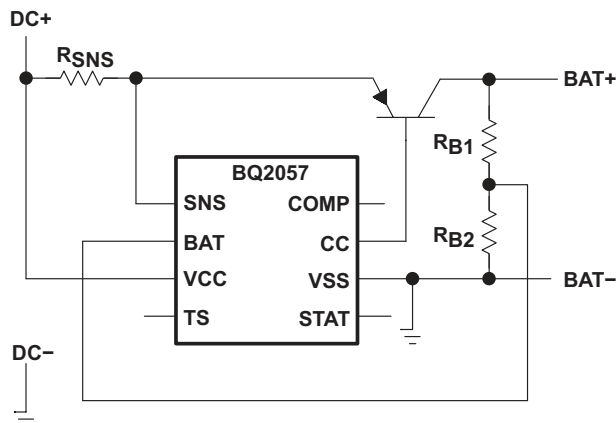
Other regulation voltages can be achieved by adding a voltage divider between the positive and negative terminals of the battery pack and using BQ2057T or BQ2057W. The voltage divider presents scaled battery-pack voltage to BAT input. (See [Figure 10-7](#) and [Figure 10-8](#).) The resistor values RB1 and RB2 for the voltage divider are calculated by the following equation:

$$\frac{R_{B1}}{R_{B2}} = \left( N \times \frac{V_{(CELL)}}{V_{O(REG)}} \right) - 1 \quad (2)$$

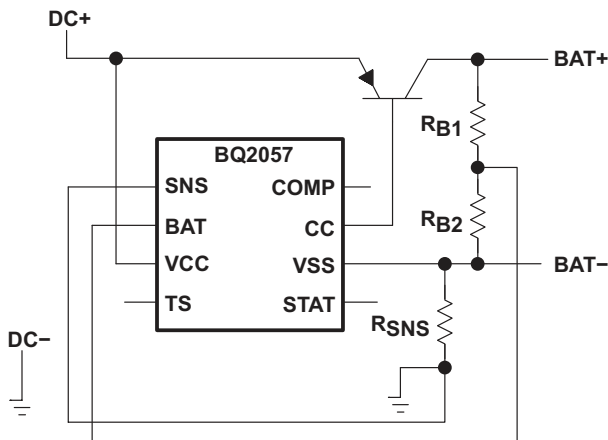
Where:

N = Number of cells in series

V<sub>(CELL)</sub> = Desired regulation voltage per cell



**Figure 10-7. Optional Voltage Divider for Nonstandard Regulation Voltage, (High-Side Current Sensing)**



**Figure 10-8. Optional Voltage Divider for Nonstandard Regulation Voltage, (Low-Side Current Sensing)**

### 10.1.5 Charge Termination and Recharge

The BQ2057 monitors the charging current during the voltage-regulation phase. The BQ2057 declares a done condition and terminates charge when the current tapers off to the charge termination threshold,  $I_{(TERM)}$ . A new charge cycle begins when the battery voltage falls below the  $V_{(RCH)}$  threshold.

### 10.1.6 Battery Temperature Monitoring

The BQ2057 continuously monitors temperature by measuring the voltage between the TS and VSS pins. A negative- or a positive-temperature coefficient thermistor (NTC, PTC) and an external voltage divider typically develop this voltage. (See [Figure 10-9](#).) The BQ2057 compares this voltage against its internal  $V_{(TS1)}$  and  $V_{(TS2)}$  thresholds to determine if charging is allowed. (See [Figure 10-10](#).) The temperature sensing circuit is immune to any fluctuation in  $V_{CC}$ , since both the external voltage divider and the internal thresholds ( $V_{(TS1)}$  and  $V_{(TS2)}$ ) are referenced to  $V_{CC}$ .

The resistor values of  $R_{(T1)}$  and  $R_{(T2)}$  are calculated by the following equations:

For NTC Thermistors

$$R_{T1} = \frac{5 \times R_{TH} \times R_{TC}}{3 \times (R_{TC} - R_{TH})} \quad (3)$$

$$R_{T1} = \frac{5 \times R_{TH} \times R_{TC}}{3 \times (R_{TC} - R_{TH})} \quad (4)$$

For PTC Thermistors

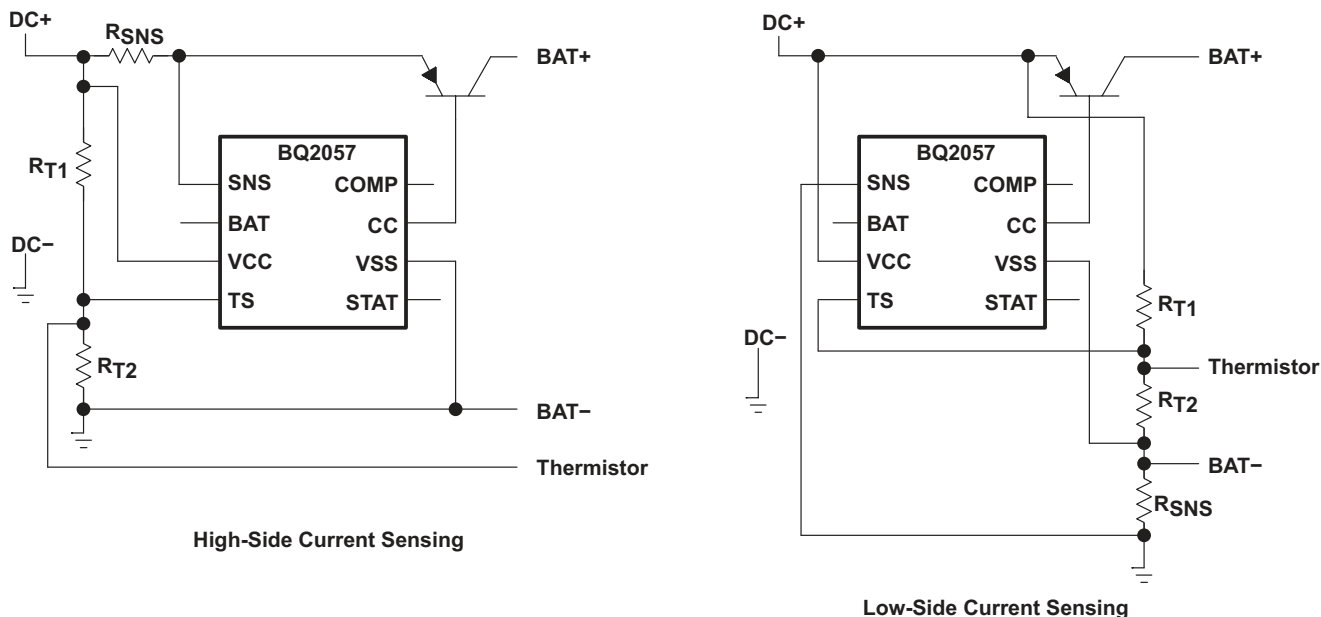
$$R_{T1} = \frac{5 \times R_{TH} \times R_{TC}}{3 \times (R_{TH} - R_{TC})} \quad (5)$$

$$R_{T2} = \frac{5 \times R_{TH} \times R_{TC}}{\left[ (2 \times R_{TH}) - (7 \times R_{TC}) \right]} \quad (6)$$

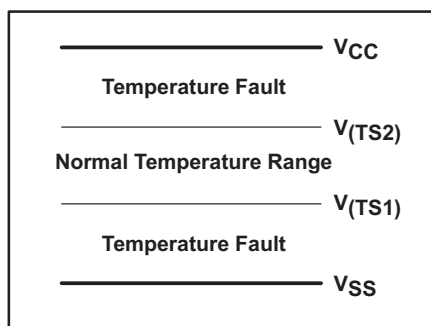
Where  $R_{(TC)}$  is the cold temperature resistance and  $R_{(TH)}$  is the hot temperature resistance of thermistor, as specified by the thermistor manufacturer.

$R_{T1}$  or  $R_{T2}$  can be omitted If only one temperature (hot or cold) setting is required. Applying a voltage between the  $V_{(TS1)}$  and  $V_{(TS2)}$  thresholds to pin TS disables the temperature-sensing feature.





**Figure 10-9. Temperature Sensing Circuits**



**Figure 10-10. BQ2057 TS Input Thresholds**

### 10.1.7 Charge Inhibit Function

The TS pin can be used as charge-inhibit input. The user can inhibit charge by connecting the TS pin to VCC or VSS (or any level outside the  $V_{(TS1)}$  to  $V_{(TS2)}$  thresholds). Applying a voltage between the  $V_{(TS1)}$  and  $V_{(TS2)}$  thresholds to pin TS returns the charger to normal operation.

### 10.1.8 Charge Status Indication

The BQ2057 reports the status of the charger on the 3-state STAT pin. The following table summarized the operation of the STAT pin.

| CONDITION                         | STAT PIN |
|-----------------------------------|----------|
| Battery conditioning and charging | High     |
| Charge complete (Done)            | Low      |
| Temperature fault or sleep mode   | Hi-Z     |

The STAT pin can be used to drive a single LED (Figure 10-1), dual-chip LEDs (Figure 4) or for interface to a host or system processor (Figure 10-11). When interfacing the BQ2057 to a processor, the user can use an output port, as shown in Figure 10-11, to recognize the Hi-Z state of the STAT pin. In this configuration, the user needs to read the input pin, toggle the output port and read the STAT pin again. In a Hi-Z condition, the input port always matches the signal level on the output port.

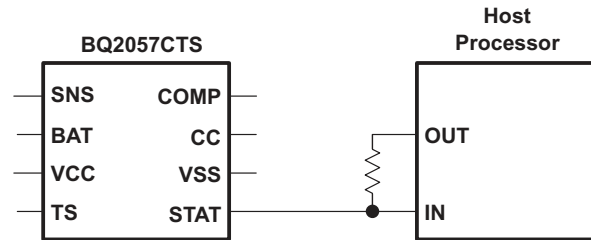


Figure 10-11. Interfacing the BQ2057 to a Host Processor

### 10.1.9 Low-power Sleep Mode

The BQ2057 enters the sleep mode if the VCC falls below the voltage at the BAT input. This feature prevents draining the battery pack during the absence of VCC.

#### 10.1.10 Selecting an External Pass-Transistor

The BQ2057 is designed to work with both PNP transistor and P-channel MOSFET. The device should be chosen to handle the required power dissipation, given the circuit parameters, PCB layout and heat sink configuration. The following examples illustrate the design process for either device:

**PNP transistor:** Selection steps for a PNP bipolar transistor: Example:  $V_I = 4.5\text{ V}$ ,  $I_{(REG)} = 1\text{ A}$ , 4.2-V single-cell Li-Ion (bq2057C).  $V_I$  is the input voltage to the charger and  $I_{(REG)}$  is the desired charge current (see Figure 10-1).

1. Determine the maximum power dissipation,  $P_D$ , in the transistor. The worst case power dissipation happens when the cell voltage,  $V_{(BAT)}$ , is at its lowest (typically 3 V at the beginning of current regulation phase) and  $V_I$  is at its maximum.

Where  $V_{CS}$  is the voltage drop across the current sense resistor.

$$P_D = (V_I - V_{CS} - V_{(BAT)}) \times I_{REG}$$

$$P_D = (4.5 - 0.1 - 3) \times 1\text{ A}$$

$$P_D = 1.4\text{ W} \quad (7)$$

2. Determine the package size needed in order to keep the junction temperature below the manufacturer's recommended value,  $T_{(J)max}$ . Calculate the total theta,  $\theta(^{\circ}\text{C/W})$ , needed.

$$\theta_{JC} = \frac{(T_{(J)max} - T_{A(max)})}{P_D}$$

$$\theta_{JC} = \frac{(150 - 40)}{1.4}$$

$$\theta_{JC} = 78^{\circ}\text{C} / \text{W} \quad (8)$$

Now choose a device package with a theta at least 10% below this value to account for additional thetas other than the device. A SOT223 package, for instance, has typically a theta of  $60^{\circ}\text{C/W}$ .

3. Select a collector-emitter voltage,  $V_{(CE)}$ , rating greater than the maximum input voltage. A 15-V device will be adequate in this example.
4. Select a device that has at least 50% higher drain current  $I_C$  rating than the desired charge current  $I_{(REG)}$ .
5. Using Equation 9, calculate the minimum beta ( $\beta$  or  $h_{FE}$ ) needed:

$$\beta_{min} = \frac{I_{Cmax}}{I_B}$$

$$\beta_{min} = \frac{1}{0.035}$$

$$\beta_{min} = 28 \quad (9)$$

where  $I_{\max(C)}$  is the maximum collector current (in this case same as  $I_{(REG)}$ ), and  $I_B$  is the base current (chosen to be 35 mA in this example).

### Note

The beta of a transistor drops off by a factor of 3 over temperature and also drops off with load. Therefore, note the beta of device at  $I_{(REG)}$  and the minimum ambient temperature when choosing the device. This beta should be larger than the minimum required beta.

Now choose a PNP transistor that is rated for  $V_{(CE)} \geq 15$  V,  $\theta_{JC} \leq 78^\circ\text{C/W}$ ,  $I_C \geq 1.5$  A,  $\beta_{\min} \geq 28$  and that is in a SOT223 package.

**P-channel MOSFET:** Selection steps for a P-channel MOSFET: Example:  $V_I = 5.5$  V,  $I_{(REG)} = 500$  mA, 4.2-V single-cell Li-Ion (BQ2057C).  $V_I$  is the input voltage to the charger and  $I_{(REG)}$  is the desired charge current. (See Figure 10-4.)

1. Determine the maximum power dissipation,  $P_D$ , in the transistor.  
The worst case power dissipation happens when the cell voltage,  $V_{(BAT)}$ , is at its lowest (typically 3 V at the beginning of current regulation phase) and  $V_I$  is at its maximum.  
Where  $V_D$  is the forward voltage drop across the reverse-blocking diode (if one is used), and  $V_{CS}$  is the voltage drop across the current sense resistor.

$$P_D = (V_I - V_D - V_{(CS)} - V_{(BAT)}) \times I_{(REG)}$$

$$P_D = (5.5 - 0.4 - 0.1 - 3) \times 0.5 \text{ A}$$

$$P_D = 1 \text{ W}$$
(10)

2. Determine the package size needed in order to keep the junction temperature below the manufacturer's recommended value,  $T_{JMAX}$ . Calculate the total theta,  $\theta(^{\circ}\text{C/W})$ , needed.

$$\theta_{JC} = \frac{(T_{\max(J)} - T_{A(\max)})}{P_D}$$

$$\theta_{JC} = \frac{(150 - 40)}{1}$$

$$\theta_{JC} = 110^\circ\text{C/W}$$
(11)

Now choose a device package with a theta at least 10% below this value to account for additional thetas other than the device. A TSSOP-8 package, for instance, has typically a theta of  $70^\circ\text{C/W}$ .

3. Select a drain-source voltage,  $V_{(DS)}$ , rating greater than the maximum input voltage. A 12-V device will be adequate in this example.
4. Select a device that has at least 50% higher drain current ( $I_D$ ) rating than the desired charge current  $I_{(REG)}$ .
5. Verify that the available drive is large enough to supply the desired charge current.

$$V_{(GS)} = (V_D + V_{(CS)} + V_{OL(CC)}) - V_I$$

$$V_{(GS)} = (0.4 + 0.1 + 1.5) - 5.5$$

$$V_{(GS)} = -3.5$$
(12)

Where  $V_{(GS)}$  is the gate-to-source voltage,  $V_D$  is the forward voltage drop across the reverse-blocking diode (if one is used), and  $V_{CS}$  is the voltage drop across the current sense resistor, and  $V_{OL(CC)}$  is the CC pin output low voltage specification for the BQ2057.

Select a MOSFET with gate threshold voltage,  $V_{(GStH)}$ , rating less than the calculated  $V_{(GS)}$ .

Now choose a P-channel MOSFET transistor that is rated for  $V_{DS} \leq -15\text{ V}$ ,  $\theta_{JC} \leq 110^\circ\text{C/W}$ ,  $I_D \geq 1\text{ A}$ ,  $V_{(GSth)} \geq -3.5\text{ V}$  and in a TSSOP package.

#### 10.1.11 Selecting Input Capacitor

In most applications, all that is needed is a high-frequency decoupling capacitor. A 0.1- $\mu\text{F}$  ceramic, placed in proximity to VCC and VSS pins, works well. The BQ2057 works with both regulated and unregulated external dc supplies. If a nonregulated supply is chosen, the supply unit should have enough capacitance to hold up the supply voltage to the minimum required input voltage at maximum load. If not, more capacitance must be added to the input of the charger.

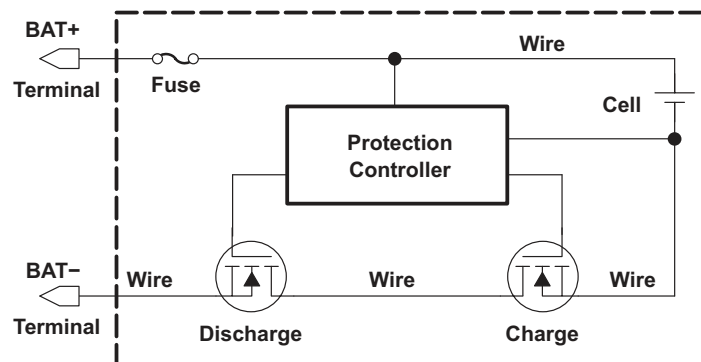
#### 10.1.12 Selecting Output Capacitor

The BQ2057 does not require any output capacitor for loop stability. The user can add output capacitance in order to control the output voltage when a battery is not present. The charger quickly charges the output capacitor to the regulation voltage, but the output voltage decays slowly, because of the low leakage current on the BAT pin, down to the recharge threshold. Addition of a 0.1- $\mu\text{F}$  ceramic capacitor, for instance, results in a 100-mV(pp) ripple waveform, with an approximate frequency of 25 Hz. Higher capacitor values can be used if a lower frequency is desired.

#### 10.1.13 Automatic Charge-rate Compensation

To reduce charging time, the BQ2057 uses the proprietary AutoComp technique to compensate safely for internal impedance of the battery pack. The AutoComp feature is disabled by connecting the COMP pin to VCC in high-side current-sensing configuration, and to VSS in low-side current-sensing configuration. The COMP pin must not be left floating.

Figure 10-12 outlines the major components of a single-cell Li-Ion battery pack. The Li-Ion battery pack consists of a cell, protection circuit, fuse, connector, current sense-resistors, and some wiring. Each of these components contains some resistance. Total impedance of the battery pack is the sum of the minimum resistances of all battery-pack components. Using the minimum resistance values reduces the odds for overcompensating. Overcompensating may activate the safety circuit of the battery pack.



**Figure 10-12. Typical Components of a Single-Cell Li-Ion Pack**

Compensation is achieved through input pin COMP (Figure 10-13). A portion of the current-sense voltage, presented through this pin, is scaled by a factor of  $G(\text{COMP})$  and summed with the regulation threshold,  $V_{O(\text{REG})}$ . This process increases the output voltage to compensate for the battery pack's internal impedance and for undesired voltage drops in the circuit.

AutoComp setup requires the following information:

- Total impedance of battery pack ( $Z_{(\text{PACK})}$ )
- Maximum charging current ( $I_{(\text{REG})}$ )

The voltage drop across the internal impedance of battery pack,  $V_{(Z)}$ , can then be calculated using Equation 13:

$$V_{(Z)} = Z_{(\text{PACK})} \times I_{(\text{REG})} \quad (13)$$

The required compensation is then calculated using [Equation 14](#):

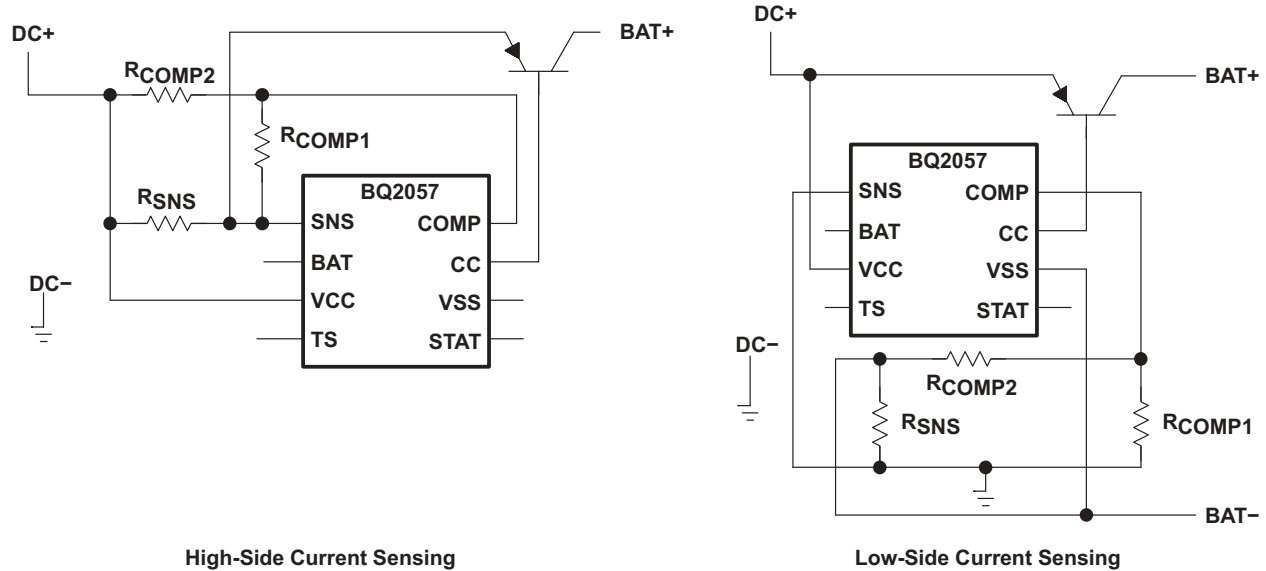
$$V_{(COMP)} = \frac{V_{(Z)}}{G_{(COMP)}}$$

$$V_{(PACK)} = V_{O(REG)} + (G_{(COMP)} \times V_{(COMP)}) \quad (14)$$

Where  $V_{(COMP)}$  is the voltage on COMP pin. This voltage is referenced to VCC in high-side current sensing configuration and to VSS for low-side sensing.  $V_{(PACK)}$  is the voltage across the battery pack.

The values of  $R_{(COMP1)}$  and  $R_{(COMP2)}$  can be calculated using [Equation 15](#):

$$\frac{V_{(COMP)}}{V_{(SNS)}} = \frac{R_{COMP2}}{R_{COMP1} + R_{COMP2}} \quad (15)$$



**Figure 10-13. AutoComp Circuits**

The following example illustrates these calculations:

Assume  $Z_{(PACK)} = 100 \text{ m}\Omega$ ,  $I_{(REG)} = 500 \text{ mA}$ , high-side current sensing BQ2057C

$$V_{(Z)} = Z_{(PACK)} \times I_{(REG)}$$

$$V_{(Z)} = 0.1 \times 0.5$$

$$V_{(Z)} = 50 \text{ mV} \quad (16)$$

$$V_{(COMP)} = \frac{V_{(Z)}}{G_{(COMP)}}$$

$$V_{(COMP)} = \frac{0.05}{2.2}$$

$$V_{(COMP)} = 22.7 \text{ mV}$$

Let  $R_{COMP2} = 10 \text{ k}\Omega$  (17)

$$R_{COMP1} = \frac{R_{COMP2} \times (V_{(SNS)} - V_{(COMP)})}{V_{(COMP)}}$$

$$R_{COMP1} = 10k \times \frac{(105 \text{ mV} - 22.7 \text{ mV})}{22.7 \text{ mV}}$$

$$R_{COMP1} = 36.25 \text{ k}\Omega$$

(18)

Use the closest standard value (36.0 kΩ) for  $R_{COMP1}$ .

## 10.2 Typical Application

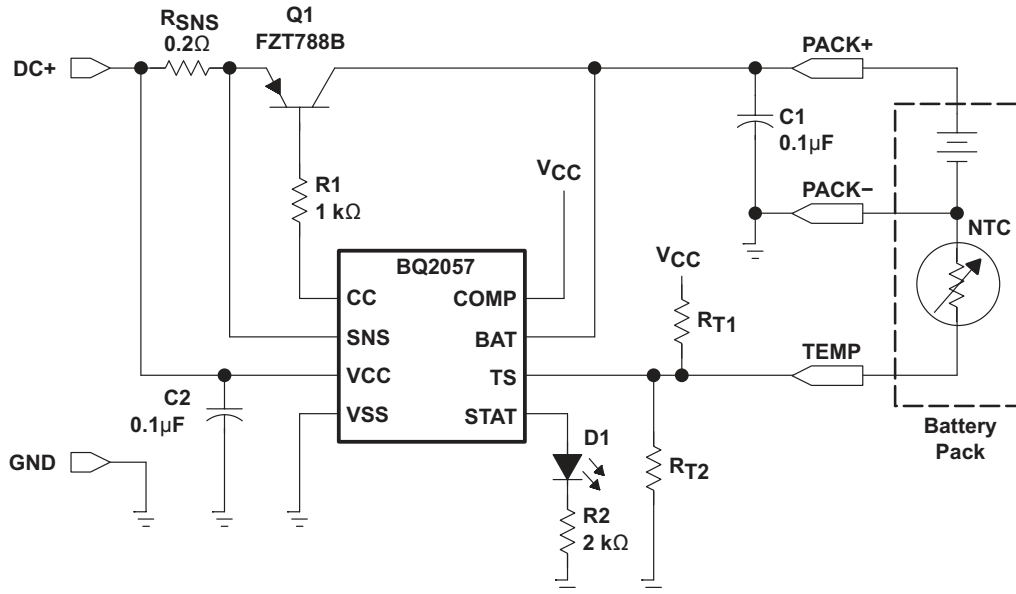


Figure 10-14. Low Dropout Single- or Two-Cell Li-Ion/Li-Pol Charger

### 10.2.1 Design Requirements

The design requirements include the following:

- Supply voltage = 12 V
- Dual cell Li-ion 8.2 V
- Fast charge current = 600 mA
  - High-side current sense
- Termination current = 10% (default)
- Precharge current = 10% (default)
- TS – Battery temperature sense = 10 kΩ (103AT, NTC)
  - 0°C cold and 60°C hot

### 10.2.2 Detailed Design Procedure

The detailed design procedure is listed below:

- Single cell Li-ion, 8.2 V - BQ2057T
- Pass transistor
  - For PNP BJT, see section 10.1.10 PNP transistor
  - For P-Type MOSFET, see section 10.1.10 P-channel MOSFET
- Fast charge current, see equation 1
  - $R_{sns} = V_{sns} / I_{out} = 125 \text{ mV} / 600 \text{ mA} = 0.2 \Omega$
- Termination Current default to 10% of fast charge current

- Pre-Charge Current default to 10% of fast charge current.
- TS – apply Equations 3 and 4 to calculate RT1 and RT2
  - RT1 = 5600  $\Omega$  ( 5.62 k $\Omega$ ), RT2 = 12326  $\Omega$  (12.4 k $\Omega$ )

### 10.2.3 Application Curves

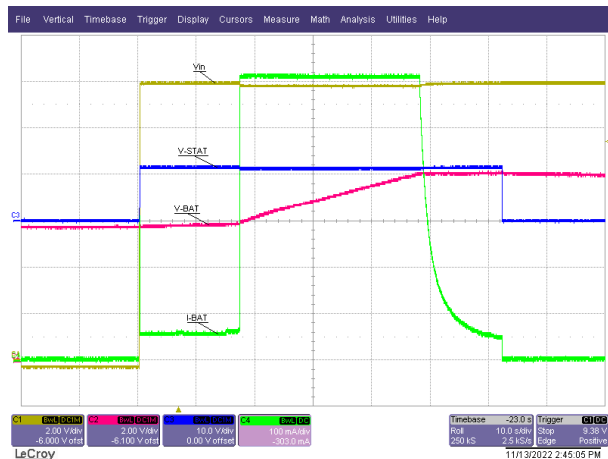


Figure 10-15. Charge Profile with Battery Simulator

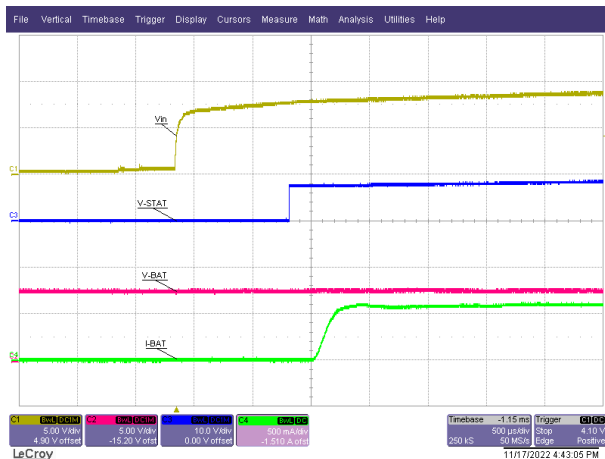


Figure 10-16. Charge Profile with Battery Simulator - STAT

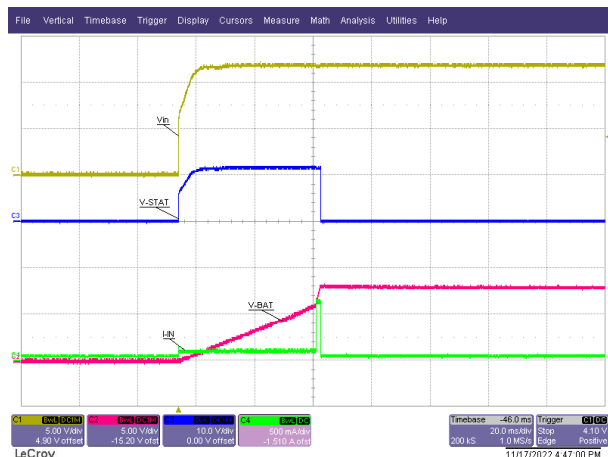


Figure 10-17. Power On - No Battery

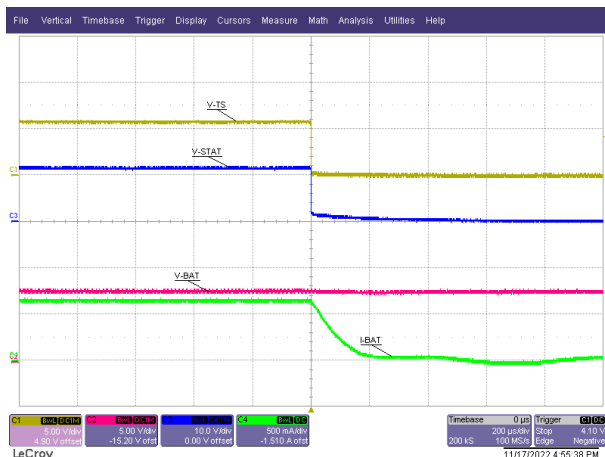


Figure 10-18. Shutdown - TS Pin Low

## 11 Power Supply Recommendations

The devices are designed to operate from an input voltage supply range between 4.5 V and 15 V and current capability of at least the maximum designed charge current. This input supply should be well regulated. If located more than a few inches from the device, VCC and GND terminals, a larger capacitor is recommended.



## **12 Layout**

### **12.1 Layout Guidelines**

#### **12.1.1 Power FET**

The external pass PNP transistor or P-channel MOSFET will have high thermal rise, good heat sinking will be required.

#### **12.1.2 Current Sense**

The BQ2057 regulates current by sensing, on the SNS pin, the voltage drop developed across an external sense resistor. The sense resistor must be placed between the supply voltage (Vcc) and the input of the IC (IN pins).

#### **12.1.3 Voltage Sense**

To achieve maximum voltage regulation accuracy, the BQ2057 uses the feedback on the BAT pin. Externally, this pin should be connected as close to the battery cell terminals as possible. For additional safety, a 10-k $\Omega$  internal pullup resistor is connected between the VSENSE and OUT pins.

#### **12.1.4 Enable (TS)**

The TS pin can be used as charge-inhibit. Pulling up to VCC or pulling down to VSS places the device in a low-power standby mode.

## 12.2 Layout Example

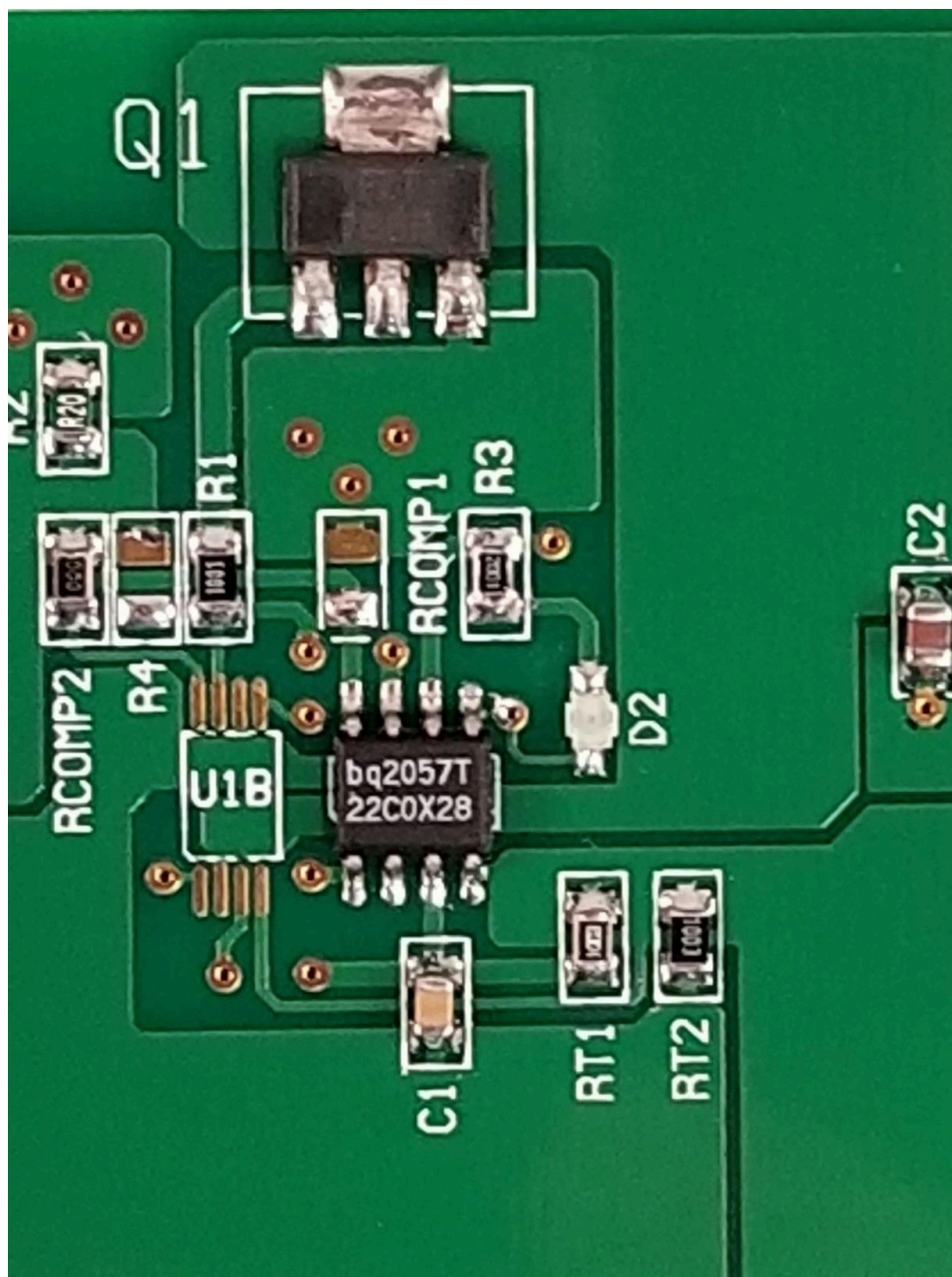
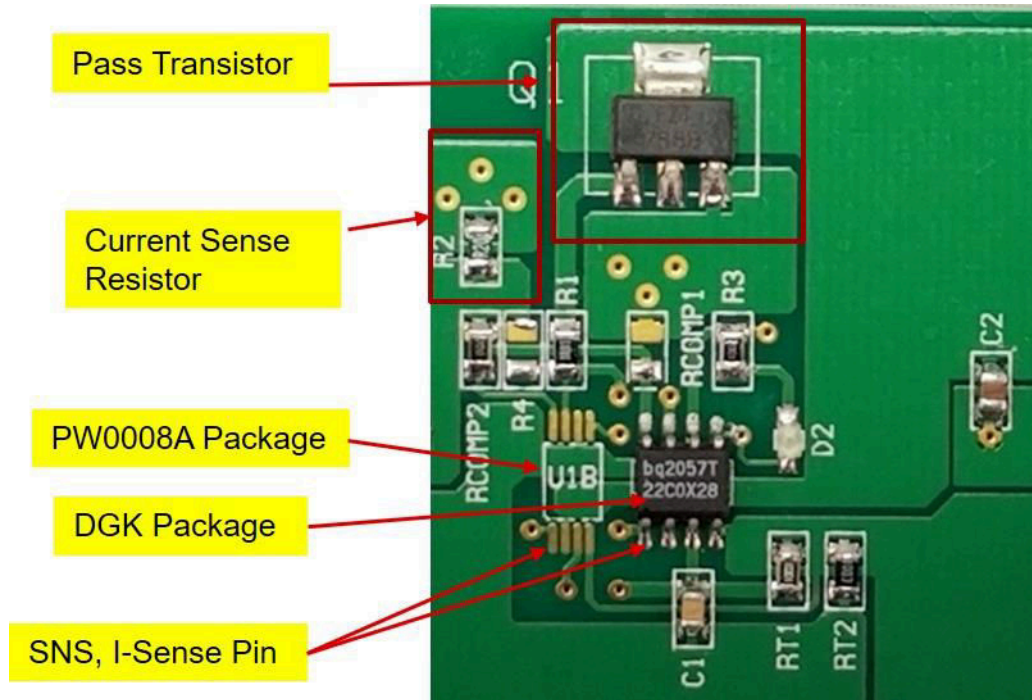


Figure 12-1. Layout Example



**Figure 12-2. Layout Example**

## 13 Device and Documentation Support

### 13.1 Device Support

#### 13.1.1 Third-Party Products Disclaimer

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#### 13.2 Receiving Notification of Documentation Updates

To receive notification of documentation updates, navigate to the device product folder on [ti.com](http://ti.com). Click on *Subscribe to updates* to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

#### 13.3 Support Resources

[TI E2E™ support forums](#) are an engineer's go-to source for fast, verified answers and design help — straight from the experts. Search existing answers or ask your own question to get the quick design help you need.

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#### 13.4 Trademarks

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All trademarks are the property of their respective owners.

#### 13.5 Electrostatic Discharge Caution



This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

#### 13.6 Glossary

[TI Glossary](#) This glossary lists and explains terms, acronyms, and definitions.

## 14 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

## PACKAGING INFORMATION

| Orderable Device | Status<br>(1) | Package Type | Package<br>Drawing | Pins | Package<br>Qty | Eco Plan<br>(2) | Lead finish/<br>Ball material<br>(6) | MSL Peak Temp<br>(3) | Op Temp (°C) | Device Marking<br>(4/5) | Samples                 |
|------------------|---------------|--------------|--------------------|------|----------------|-----------------|--------------------------------------|----------------------|--------------|-------------------------|-------------------------|
| BQ2057CDGK       | ACTIVE        | VSSOP        | DGK                | 8    | 80             | RoHS & Green    | NIPDAUAG                             | Level-2-260C-1 YEAR  | -20 to 70    | 2057C                   | <a href="#">Samples</a> |
| BQ2057CDGKR      | ACTIVE        | VSSOP        | DGK                | 8    | 2500           | RoHS & Green    | NIPDAUAG                             | Level-2-260C-1 YEAR  | -20 to 70    | 2057C                   | <a href="#">Samples</a> |
| BQ2057CSN        | ACTIVE        | SOIC         | D                  | 8    | 75             | RoHS & Green    | NIPDAU                               | Level-1-260C-UNLIM   | -20 to 70    | 2057C                   | <a href="#">Samples</a> |
| BQ2057CSNTR      | ACTIVE        | SOIC         | D                  | 8    | 2500           | RoHS & Green    | NIPDAU                               | Level-1-260C-UNLIM   | -20 to 70    | 2057C                   | <a href="#">Samples</a> |
| BQ2057CTS        | ACTIVE        | TSSOP        | PW                 | 8    | 150            | RoHS & Green    | NIPDAU                               | Level-2-260C-1 YEAR  | -20 to 70    | 2057C                   | <a href="#">Samples</a> |
| BQ2057CTSTR      | ACTIVE        | TSSOP        | PW                 | 8    | 2000           | RoHS & Green    | NIPDAU                               | Level-2-260C-1 YEAR  | -20 to 70    | 2057C                   | <a href="#">Samples</a> |

(1) The marketing status values are defined as follows:

**ACTIVE:** Product device recommended for new designs.

**LIFEBUY:** TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

**NRND:** Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

**PREVIEW:** Device has been announced but is not in production. Samples may or may not be available.

**OBsolete:** TI has discontinued the production of the device.

(2) **RoHS:** TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

**RoHS Exempt:** TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

**Green:** TI defines "Green" to mean the content of Chlorine (Cl) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

(3) MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

(4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

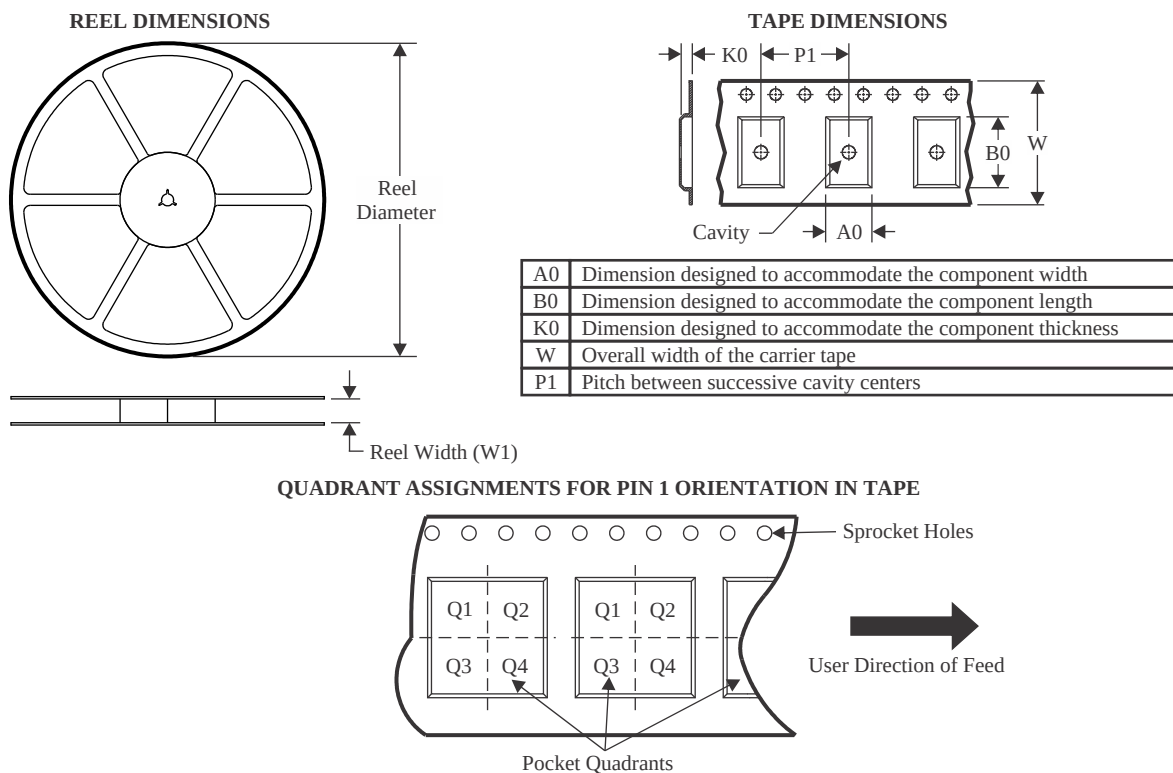
(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

(6) Lead finish/Ball material - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

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## TAPE AND REEL INFORMATION

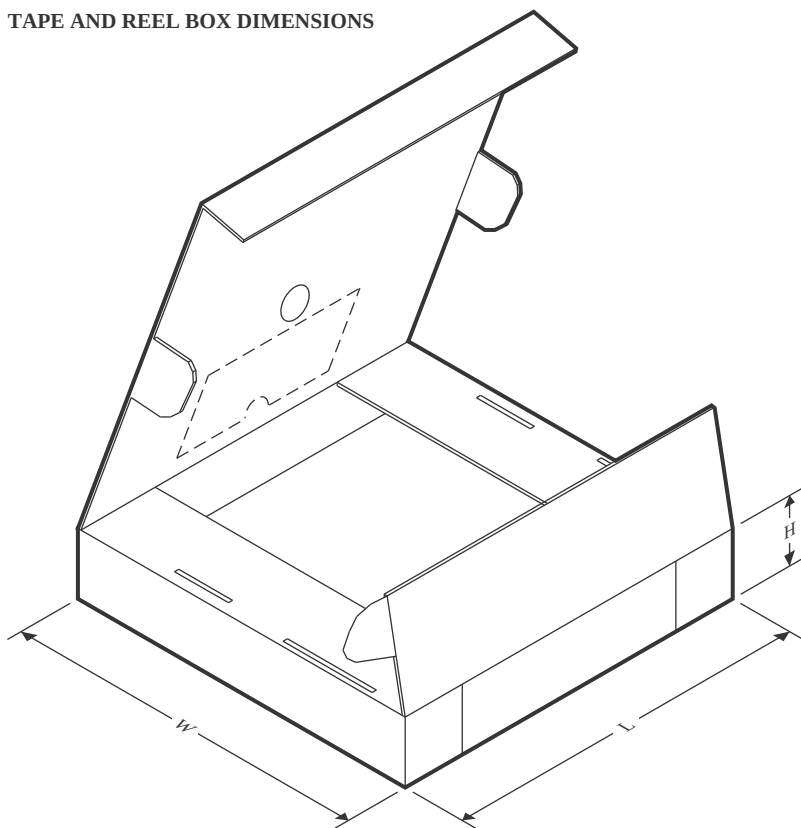


\*All dimensions are nominal

| Device      | Package Type | Package Drawing | Pins | SPQ  | Reel Diameter (mm) | Reel Width W1 (mm) | A0 (mm) | B0 (mm) | K0 (mm) | P1 (mm) | W (mm) | Pin1 Quadrant |
|-------------|--------------|-----------------|------|------|--------------------|--------------------|---------|---------|---------|---------|--------|---------------|
| BQ2057CDGKR | VSSOP        | DGK             | 8    | 2500 | 330.0              | 12.4               | 5.3     | 3.4     | 1.4     | 8.0     | 12.0   | Q1            |
| BQ2057CSNTR | SOIC         | D               | 8    | 2500 | 330.0              | 12.4               | 6.4     | 5.2     | 2.1     | 8.0     | 12.0   | Q1            |
| BQ2057CTSTR | TSSOP        | PW              | 8    | 2000 | 330.0              | 12.4               | 7.0     | 3.6     | 1.6     | 8.0     | 12.0   | Q1            |



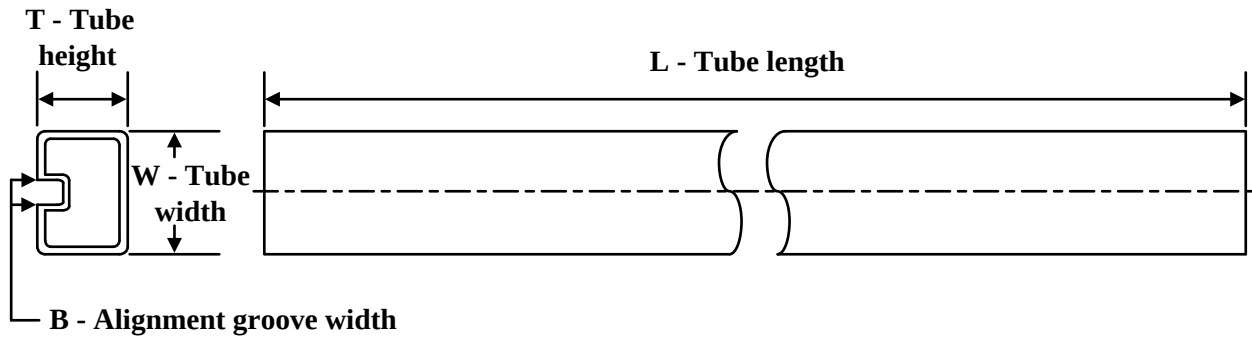
## TAPE AND REEL BOX DIMENSIONS



\*All dimensions are nominal

| Device      | Package Type | Package Drawing | Pins | SPQ  | Length (mm) | Width (mm) | Height (mm) |
|-------------|--------------|-----------------|------|------|-------------|------------|-------------|
| BQ2057CDGKR | VSSOP        | DGK             | 8    | 2500 | 367.0       | 367.0      | 35.0        |
| BQ2057CSNTR | SOIC         | D               | 8    | 2500 | 367.0       | 367.0      | 35.0        |
| BQ2057CTSTR | TSSOP        | PW              | 8    | 2000 | 367.0       | 367.0      | 35.0        |

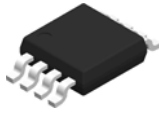
## TUBE



\*All dimensions are nominal

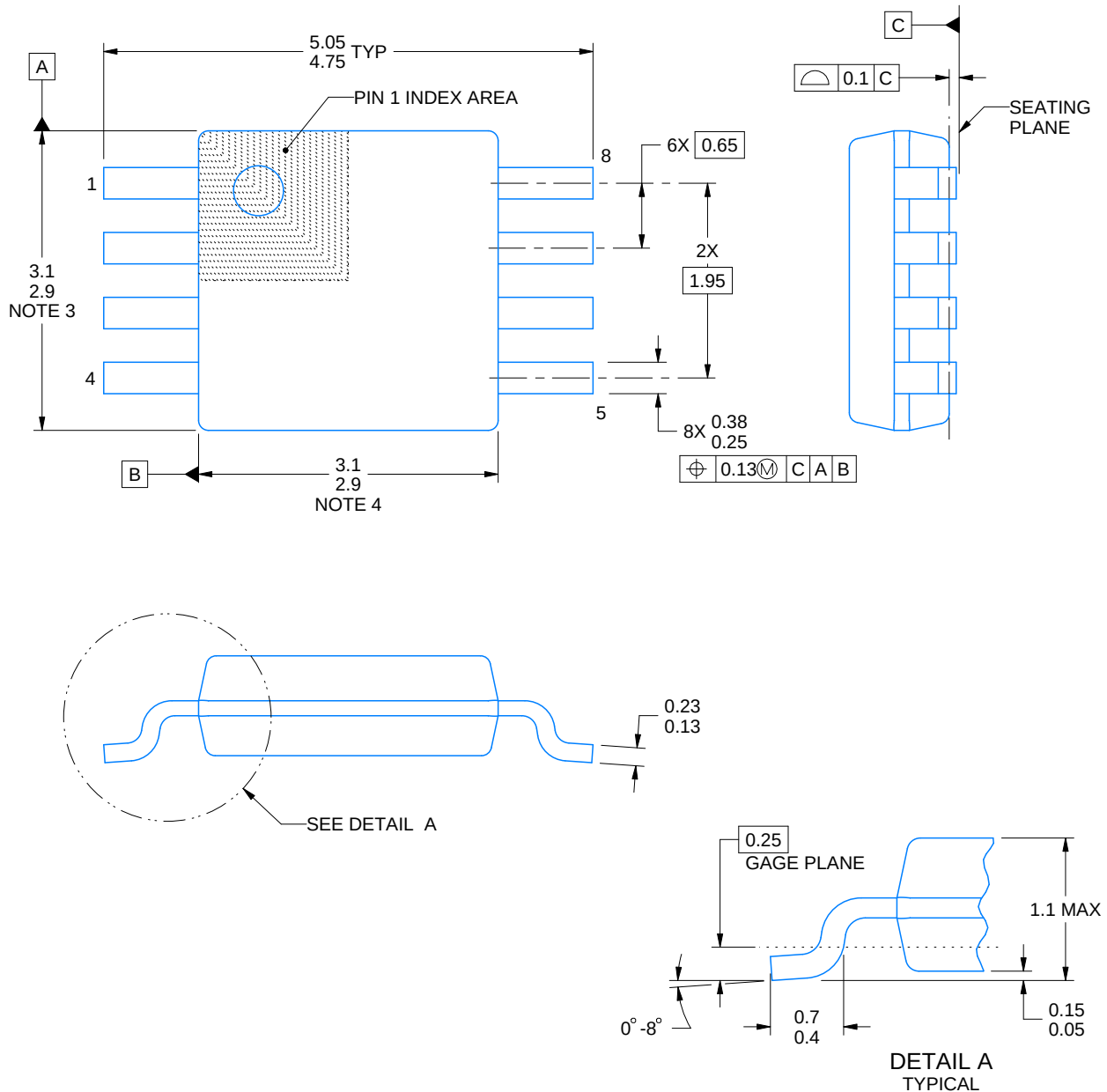
| Device     | Package Name | Package Type | Pins | SPQ | L (mm) | W (mm) | T (μm) | B (mm) |
|------------|--------------|--------------|------|-----|--------|--------|--------|--------|
| BQ2057CDGK | DGK          | VSSOP        | 8    | 80  | 330.2  | 6.6    | 3005   | 1.88   |
| BQ2057CSN  | D            | SOIC         | 8    | 75  | 506.6  | 8      | 3940   | 4.32   |
| BQ2057CTS  | PW           | TSSOP        | 8    | 150 | 508    | 8.5    | 3250   | 2.8    |

DGK0008A



**PACKAGE OUTLINE**  
**VSSOP - 1.1 mm max height**

SMALL OUTLINE PACKAGE



4214862/A 04/2023

NOTES:

PowerPAD is a trademark of Texas Instruments.

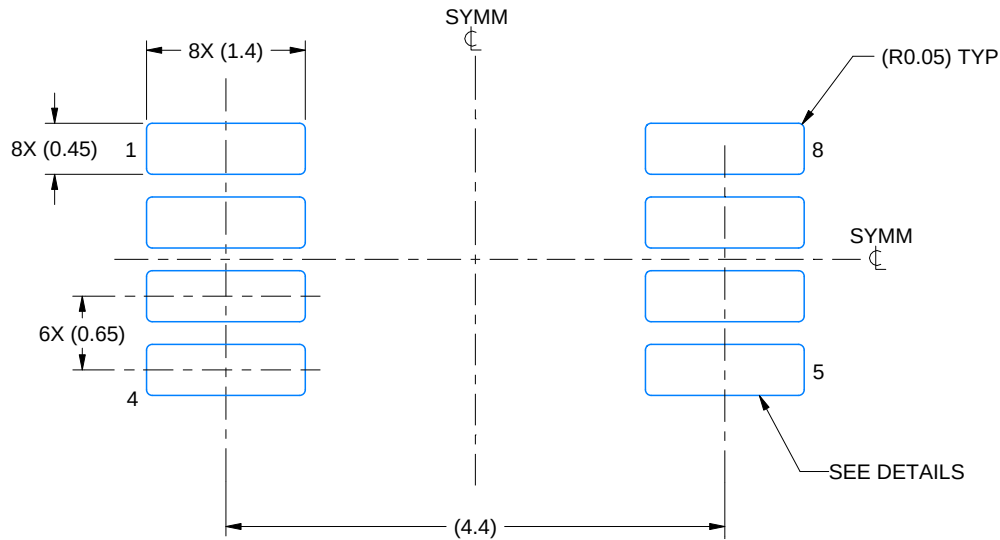
1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 mm per side.
4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
5. Reference JEDEC registration MO-187.

# EXAMPLE BOARD LAYOUT

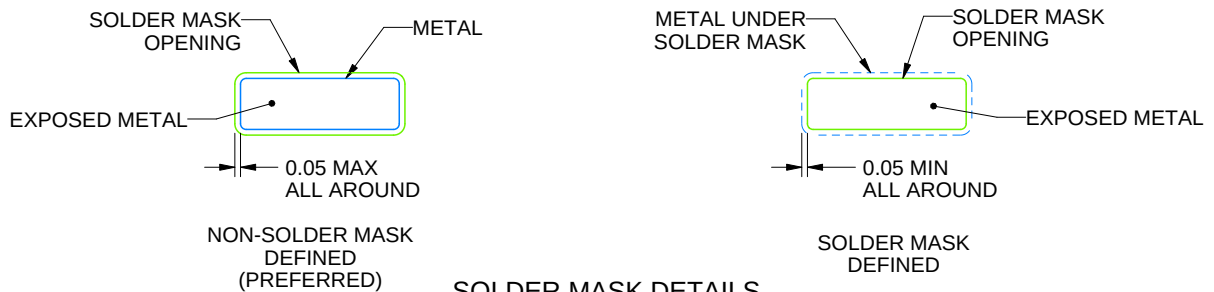
DGK0008A

<sup>TM</sup> VSSOP - 1.1 mm max height

SMALL OUTLINE PACKAGE



LAND PATTERN EXAMPLE  
EXPOSED METAL SHOWN  
SCALE: 15X



SOLDER MASK DETAILS

4214862/A 04/2023

NOTES: (continued)

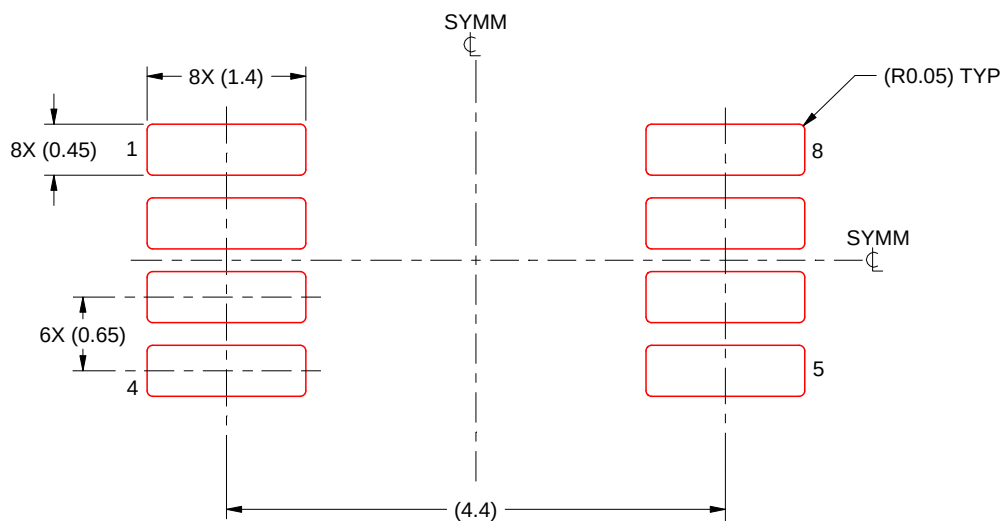
6. Publication IPC-7351 may have alternate designs.
7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.
8. Vias are optional depending on application, refer to device data sheet. If any vias are implemented, refer to their locations shown on this view. It is recommended that vias under paste be filled, plugged or tented.
9. Size of metal pad may vary due to creepage requirement.

## EXAMPLE STENCIL DESIGN

DGK0008A

™ VSSOP - 1.1 mm max height

SMALL OUTLINE PACKAGE

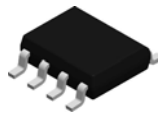


SOLDER PASTE EXAMPLE  
SCALE: 15X

4214862/A 04/2023

NOTES: (continued)

11. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
12. Board assembly site may have different recommendations for stencil design.

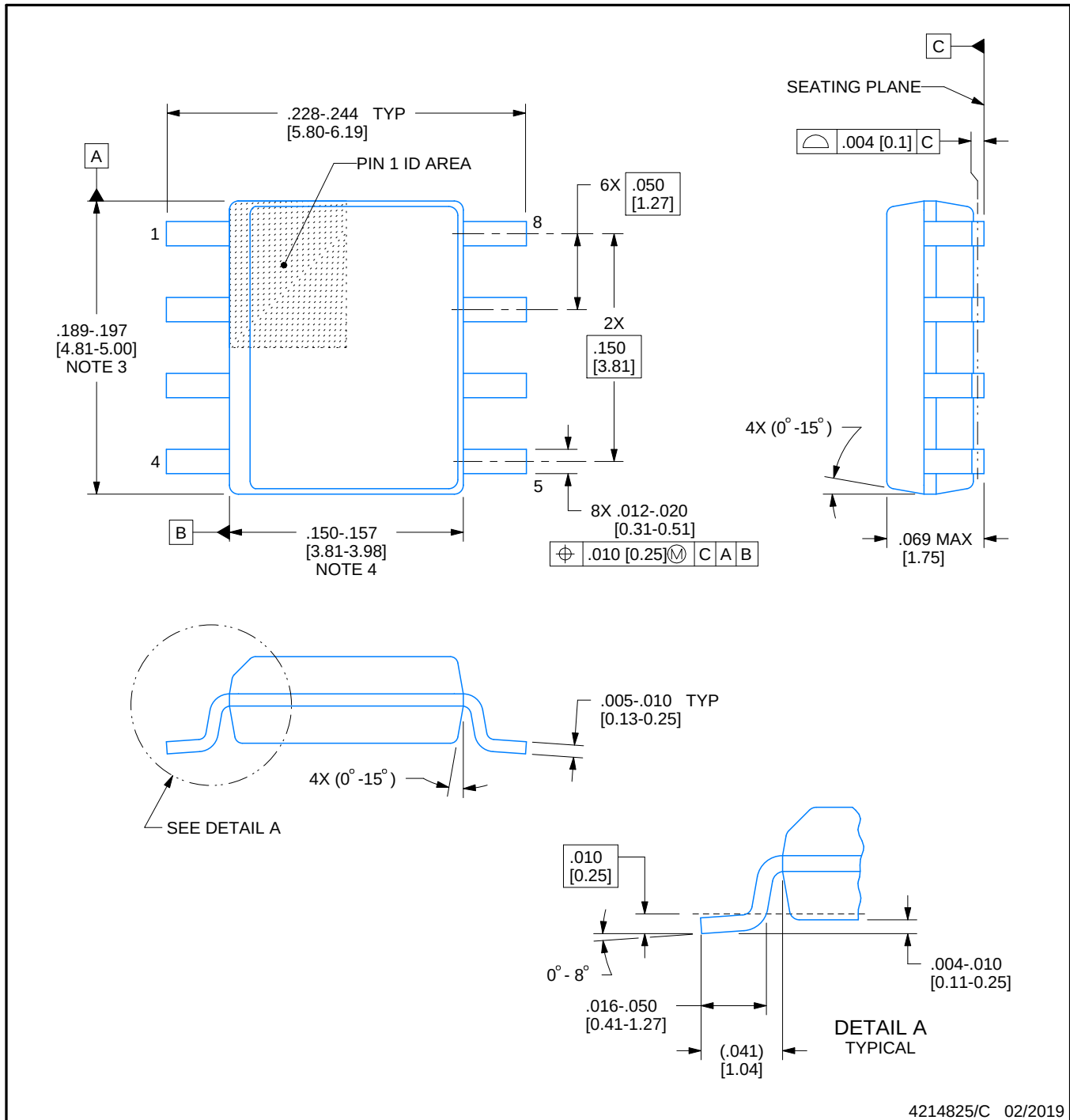


**D0008A**

# PACKAGE OUTLINE

**SOIC - 1.75 mm max height**

SMALL OUTLINE INTEGRATED CIRCUIT



4214825/C 02/2019

## NOTES:

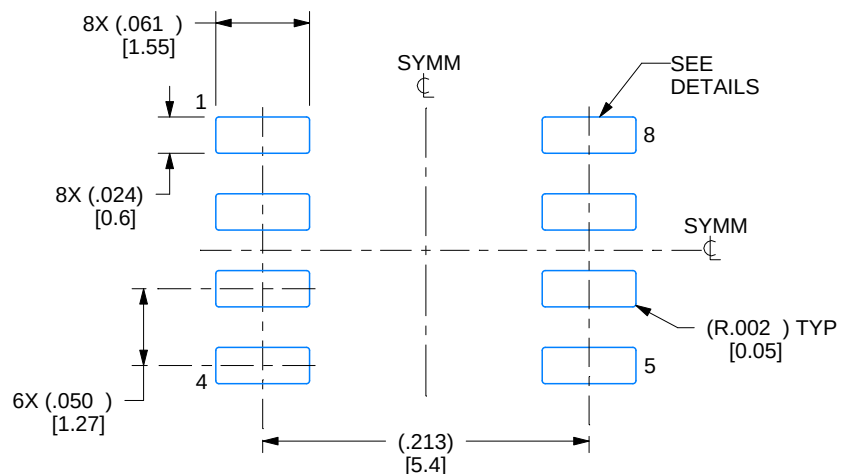
1. Linear dimensions are in inches [millimeters]. Dimensions in parenthesis are for reference only. Controlling dimensions are in inches. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed .006 [0.15] per side.
4. This dimension does not include interlead flash.
5. Reference JEDEC registration MS-012, variation AA.

# EXAMPLE BOARD LAYOUT

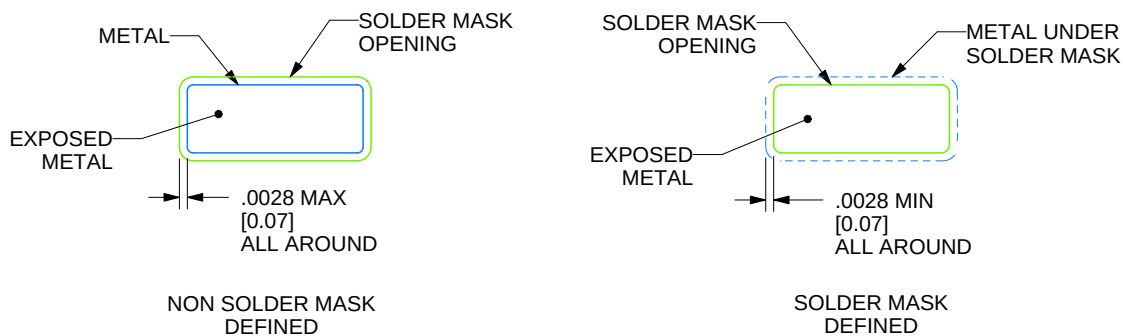
D0008A

SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT



LAND PATTERN EXAMPLE  
EXPOSED METAL SHOWN  
SCALE:8X



SOLDER MASK DETAILS

4214825/C 02/2019

NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

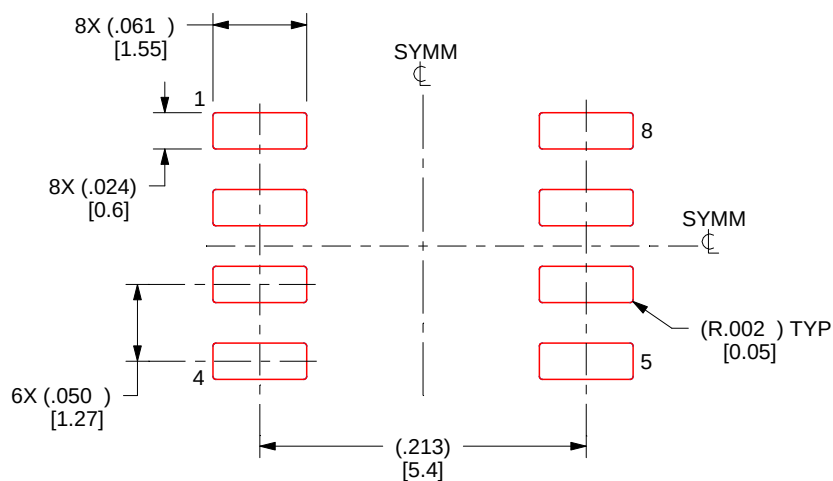
7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

## EXAMPLE STENCIL DESIGN

D0008A

SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT



SOLDER PASTE EXAMPLE  
BASED ON .005 INCH [0.125 MM] THICK STENCIL  
SCALE:8X

4214825/C 02/2019

NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
9. Board assembly site may have different recommendations for stencil design.

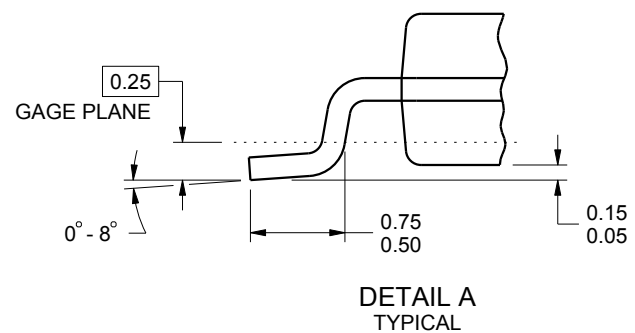
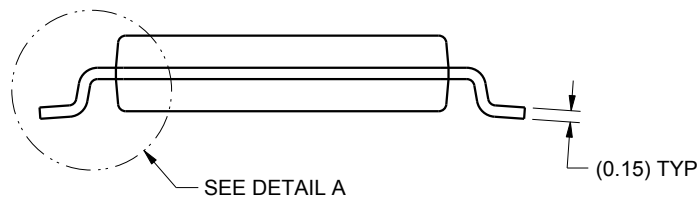
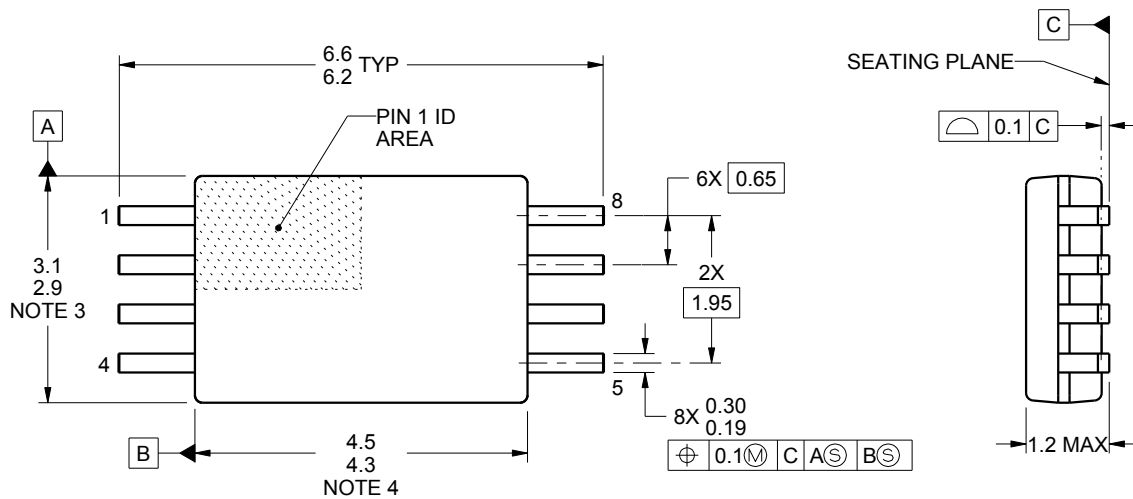


**PW0008A**

## PACKAGE OUTLINE

**TSSOP - 1.2 mm max height**

SMALL OUTLINE PACKAGE



4221848/A 02/2015

NOTES:

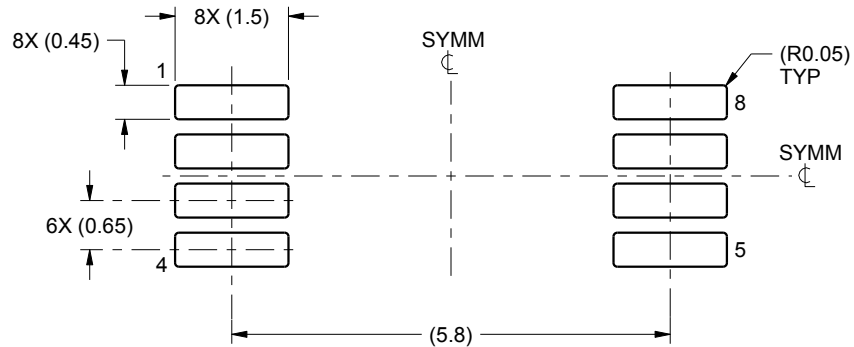
1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 mm per side.
4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
5. Reference JEDEC registration MO-153, variation AA.

# EXAMPLE BOARD LAYOUT

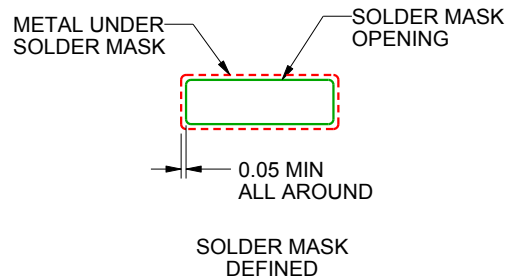
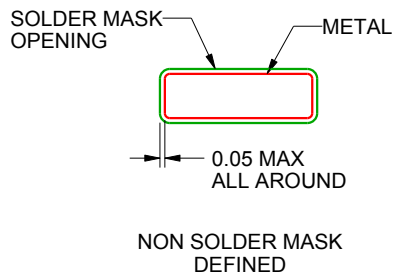
PW0008A

TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE



LAND PATTERN EXAMPLE  
SCALE:10X



SOLDER MASK DETAILS  
NOT TO SCALE

4221848/A 02/2015

NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

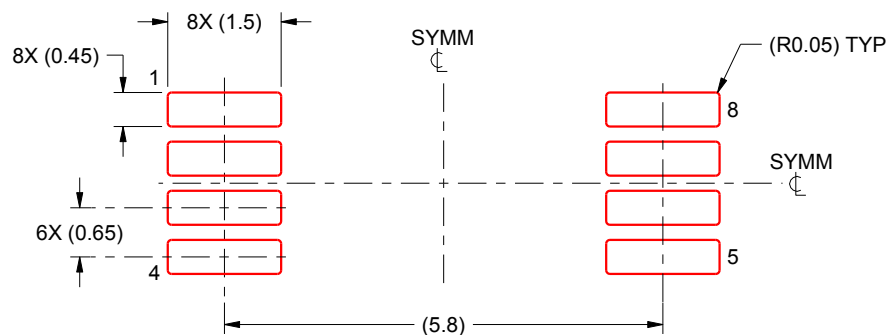
7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

## EXAMPLE STENCIL DESIGN

PW0008A

TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE



SOLDER PASTE EXAMPLE  
BASED ON 0.125 mm THICK STENCIL  
SCALE:10X

4221848/A 02/2015

NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
9. Board assembly site may have different recommendations for stencil design.

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